

Introduction

The Zynq®-7000 All Programmable SoCs are available in -3, -2, and -1 speed grades, with -3 having the highest performance. Zynq-7000 device DC and AC characteristics are specified in commercial, extended, industrial and expanded (Q-temp) temperature ranges. Except for the operating temperature range or unless otherwise noted, all the DC and AC electrical parameters are the same for a particular speed grade (that is, the timing characteristics of a -1 speed grade industrial device are the same as for a -1 speed grade commercial device). However, only selected speed grades and/or devices are available in the commercial, extended, industrial, or Q-temp temperature ranges.

All supply voltage and junction temperature specifications are representative of worst-case conditions. The parameters included are common to popular designs and typical applications.

The available device/package combinations are outlined in:

- *Zynq-7000 All Programmable SoC Overview* ([DS190](#))
- *XA Zynq-7000 All Programmable SoC Overview* ([DS188](#))
- *Defense-grade Zynq-7000Q All Programmable SoC Overview* ([DS196](#))

This Zynq-7000 AP SoC data sheet, which covers the specifications for the XC7Z010, XA7Z010, XC7Z015, XC7Z020, XA7Z020, and XQ7Z020, complements the Zynq-7000 AP SoC documentation suite available on the Xilinx website at www.xilinx.com/zynq.

DC Characteristics

Table 1: Absolute Maximum Ratings⁽¹⁾

Symbol	Description	Min	Max	Units
Processing System (PS)				
V _{CCPINT}	PS internal logic supply	−0.5	1.1	V
V _{CCPAUX}	PS auxiliary supply voltage	−0.5	2.0	V
V _{CCPLL}	PS PLL supply	−0.5	2.0	V
V _{CCO_DDR}	PS DDR I/O supply voltage	−0.5	2.0	V
V _{CCO_MIO} ⁽²⁾	PS MIO I/O supply voltage	−0.5	3.6	V
V _{PREF}	PS input reference voltage	−0.5	2.0	V
V _{PIN} ⁽²⁾⁽³⁾⁽⁴⁾⁽⁵⁾	PS MIO I/O input voltage	−0.40	V _{CCO_MIO} + 0.55	V
	PS DDR I/O input voltage	−0.55	V _{CCO_DDR} + 0.55	V
Programmable Logic (PL)				
V _{CCINT}	PL internal supply voltage	−0.5	1.1	V
V _{CCAUX}	PL auxiliary supply voltage	−0.5	2.0	V
V _{CCBRAM}	PL supply voltage for the block RAM memories	−0.5	1.1	V
V _{CCO}	PL supply voltage for 3.3V HR I/O banks	−0.5	3.6	V
V _{REF}	Input reference voltage	−0.5	2.0	V
V _{IN} ⁽³⁾⁽⁴⁾⁽⁵⁾	I/O input voltage for 3.3V HR I/O banks	−0.40	V _{CCO} + 0.55	V
	I/O input voltage (when V _{CCO} = 3.3V) for V _{REF} and differential I/O standards except TMDS_33 ⁽⁶⁾	−0.40	2.625	V

Table 1: Absolute Maximum Ratings⁽¹⁾ (Cont'd)

Symbol	Description	Min	Max	Units
V _{CCBATT}	Key memory battery backup supply	−0.5	2.0	V
GTP Transceiver (XC7Z015 Only)				
V _{MGTAVCC}	Analog supply voltage for the GTP transmitter and receiver circuits	−0.5	1.1	V
V _{MGTAVTT}	Analog supply voltage for the GTP transmitter and receiver termination circuits	−0.5	1.32	V
V _{MGTREFCLK}	Reference clock absolute input voltage	−0.5	1.32	V
V _{IN}	Receiver (RXP/RXN) and Transmitter (TXP/TXN) absolute input voltage	−0.5	1.26	V
I _{DCIN-FLOAT}	DC input current for receiver input pins DC coupled RX termination = floating	—	14	mA
I _{DCIN-MGTAVTT}	DC input current for receiver input pins DC coupled RX termination = V _{MGTAVTT}	—	12	mA
I _{DCIN-GND}	DC input current for receiver input pins DC coupled RX termination = GND	—	6.5	mA
I _{DCOUT-FLOAT}	DC output current for transmitter pins DC coupled RX termination = floating	—	14	mA
I _{DCOUT-MGTAVTT}	DC output current for transmitter pins DC coupled RX termination = V _{MGTAVTT}	—	12	mA
XADC				
V _{CCADC}	XADC supply relative to GNDADC	−0.5	2.0	V
V _{REFP}	XADC reference input relative to GNDADC	−0.5	2.0	V
Temperature				
T _{STG}	Storage temperature (ambient)	−65	150	°C
T _{SOL}	Maximum soldering temperature for Pb/Sn component bodies ⁽⁷⁾	—	+220	°C
	Maximum soldering temperature for Pb-free component bodies ⁽⁷⁾	—	+260	°C
T _j	Maximum junction temperature ⁽⁷⁾	—	+125	°C

Notes:

- Stresses beyond those listed under Absolute Maximum Ratings might cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time might affect device reliability.
- Applies to both MIO supply banks V_{CCO_MIO0} and V_{CCO_MIO1}.
- The lower absolute voltage specification always applies.
- For I/O operation, refer to the *7 Series FPGAs SelectIO Resources User Guide* (UG471) or the *Zynq-7000 All Programmable SoC Technical Reference Manual* (UG585).
- The maximum limit applies to DC signals. For maximum undershoot and overshoot AC specifications, see Table 4.
- See Table 11 for TMD5_33 specifications.
- For soldering guidelines and thermal considerations, see the *Zynq-7000 All Programmable SoC Packaging and Pinout Specification* (UG865).

Table 2: Recommended Operating Conditions⁽¹⁾⁽²⁾

Symbol	Description	Min	Typ	Max	Units
PS					
V _{CCPINT}	PS internal supply voltage	0.95	1.00	1.05	V
V _{CCPAUX}	PS auxiliary supply voltage	1.71	1.80	1.89	V
V _{CCPLL}	PS PLL supply	1.71	1.80	1.89	V
V _{CCO_DDR}	PS DDR I/O supply voltage	1.14	—	1.89	V
V _{CCO_MIO} ⁽³⁾	PS MIO I/O supply voltage for MIO banks	1.71	—	3.465	V
V _{PIN} ⁽⁴⁾	PS DDR and MIO I/O input voltage	−0.20	—	V _{CCO_DDR} + 0.20 V _{CCO_MIO} + 0.20	V

Table 2: Recommended Operating Conditions⁽¹⁾⁽²⁾ (Cont'd)

Symbol	Description	Min	Typ	Max	Units
PL					
$V_{CCINT}^{(5)}$	PL internal supply voltage	0.95	1.00	1.05	V
V_{CCAUX}	PL auxiliary supply voltage	1.71	1.80	1.89	V
$V_{CCBRAM}^{(5)}$	PL block RAM supply voltage	0.95	1.00	1.05	V
$V_{CCO}^{(6)(7)}$	PL supply voltage for 3.3V HR I/O banks	1.14	–	3.465	V
$V_{IN}^{(4)}$	I/O input voltage	–0.20	–	$V_{CCO} + 0.20$	V
	I/O input voltage (when $V_{CCO} = 3.3V$) for V_{REF} and differential I/O standards except TMD5_33 ⁽⁸⁾	–0.20	–	2.625	V
$I_{IN}^{(9)}$	Maximum current through any (PS or PL) pin in a powered or unpowered bank when forward biasing the clamp diode	–	–	10	mA
$V_{CCBATT}^{(10)}$	Battery voltage	1.0	–	1.89	V
GTP Transceiver (XC7Z015 Only)					
$V_{MGTAVCC}^{(11)}$	Analog supply voltage for the GTP transmitter and receiver circuits	0.97	1.0	1.03	V
$V_{MGTAVTT}^{(11)}$	Analog supply voltage for the GTP transmitter and receiver termination circuits	1.17	1.2	1.23	V
XADC					
V_{CCADC}	XADC supply relative to GNDADC	1.71	1.80	1.89	V
V_{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
Temperature					
T_j	Junction temperature operating range for commercial (C) temperature devices	0	–	85	°C
	Junction temperature operating range for extended (E) temperature devices	0	–	100	°C
	Junction temperature operating range for industrial (I) temperature devices	–40	–	100	°C
	Junction temperature operating range for expanded (Q) temperature devices	–40	–	125	°C

Notes:

- All voltages are relative to ground. The PL and PS share a common ground.
- For the design of the power distribution system consult the *Zynq-7000 All Programmable SoC PCB Design and Pin Planning Guide* ([UG933](#)).
- Applies to both MIO supply banks V_{CCO_MIO0} and V_{CCO_MIO1} .
- The lower absolute voltage specification always applies.
- V_{CCINT} and V_{CCBRAM} should be connected to the same supply.
- Configuration data is retained even if V_{CCO} drops to 0V.
- Includes V_{CCO} of 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.
- See [Table 11](#) for TMD5_33 specifications.
- A total of 200 mA per PS or PL bank should not be exceeded.
- V_{CCBATT} is required only when using bitstream encryption. If battery is not used, connect V_{CCBATT} to either ground or V_{CCAUX} .
- Each voltage listed requires the filter circuit described in the *7 Series FPGAs GTP Transceiver User Guide* ([UG482](#)).

Table 3: DC Characteristics Over Recommended Operating Conditions

Symbol	Description	Min	Typ ⁽¹⁾	Max	Units
V _{DRINT}	Data retention V _{CCINT} voltage (below which configuration data might be lost)	0.75	–	–	V
V _{DRI}	Data retention V _{CCAUX} voltage (below which configuration data might be lost)	1.5	–	–	V
I _{REF}	PS_DDR_VREF 0/1, PS_MIO_VREF, and V _{REF} leakage current per pin	–	–	15	μA
I _L	Input or output leakage current per pin (sample-tested)	–	–	15	μA
C _{IN} ⁽²⁾	PL die input capacitance at the pad	–	–	8	pF
C _{PIN} ⁽²⁾	PS die input capacitance at the pad	–	–	8	pF
I _{RPU}	Pad pull-up (when selected) @ V _{IN} = 0V, V _{CCO} = 3.3V	90	–	330	μA
	Pad pull-up (when selected) @ V _{IN} = 0V, V _{CCO} = 2.5V	68	–	250	μA
	Pad pull-up (when selected) @ V _{IN} = 0V, V _{CCO} = 1.8V	34	–	220	μA
	Pad pull-up (when selected) @ V _{IN} = 0V, V _{CCO} = 1.5V	23	–	150	μA
	Pad pull-up (when selected) @ V _{IN} = 0V, V _{CCO} = 1.2V	12	–	120	μA
I _{RPD}	Pad pull-down (when selected) @ V _{IN} = 3.3V	68	–	330	μA
	Pad pull-down (when selected) @ V _{IN} = 1.8V	45	–	180	μA
I _{CCADC}	Analog supply current, analog circuits in powered up state	–	–	25	mA
I _{BATT} ⁽³⁾	Battery supply current	–	–	150	nA
R _{IN_TERM} ⁽⁴⁾	Thevenin equivalent resistance of programmable input termination to V _{CCO} /2 (UNTUNED_SPLIT_40)	28	40	55	Ω
	Thevenin equivalent resistance of programmable input termination to V _{CCO} /2 (UNTUNED_SPLIT_50)	35	50	65	Ω
	Thevenin equivalent resistance of programmable input termination to V _{CCO} /2 (UNTUNED_SPLIT_60)	44	60	83	Ω
n	Temperature diode ideality factor	–	1.010	–	–
r	Temperature diode series resistance	–	2	–	Ω

Notes:

1. Typical values are specified at nominal voltage, 25°C.
2. This measurement represents the die capacitance at the pad, not including the package.
3. Maximum value specified for worst case process at 25°C.
4. Termination resistance to a V_{CCO}/2 level.

Table 4: V_{IN} Maximum Allowed AC Voltage Overshoot and Undershoot for PS I/O and 3.3V HR I/O Banks⁽¹⁾

AC Voltage Overshoot	% of UI @–40°C to 125°C	AC Voltage Undershoot	% of UI @–40°C to 125°C
$V_{CCO} + 0.55$	100	–0.40	100
		–0.45	61.7
		–0.50	25.8
		–0.55	11.0
$V_{CCO} + 0.60$	46.6	–0.60	4.77
$V_{CCO} + 0.65$	21.2	–0.65	2.10
$V_{CCO} + 0.70$	9.75	–0.70	0.94
$V_{CCO} + 0.75$	4.55	–0.75	0.43
$V_{CCO} + 0.80$	2.15	–0.80	0.20
$V_{CCO} + 0.85$	1.02	–0.85	0.09
$V_{CCO} + 0.90$	0.49	–0.90	0.04
$V_{CCO} + 0.95$	0.24	–0.95	0.02

Notes:

1. A total of 200 mA per bank should not be exceeded.

Table 5: Typical Quiescent Supply Current

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
$I_{CCPINTQ}$	PS quiescent V_{CCPINT} supply current	XC7Z010	122	122	122	mA
		XC7Z015				mA
		XC7Z020	122	122	122	mA
		XA7Z010	N/A	N/A	122	mA
		XA7Z020	N/A	N/A	122	mA
		XQ7Z020	N/A	122	122	mA
$I_{CCPAUXQ}$	PS quiescent V_{CCPAUX} supply current	XC7Z010	13	13	13	mA
		XC7Z015				mA
		XC7Z020	13	13	13	mA
		XA7Z010	N/A	N/A	13	mA
		XA7Z020	N/A	N/A	13	mA
		XQ7Z020	N/A	13	13	mA
I_{CCDDRQ}	PS quiescent V_{CCO_DDR} supply current	XC7Z010	4	4	4	mA
		XC7Z015				mA
		XC7Z020	4	4	4	mA
		XA7Z010	N/A	N/A	4	mA
		XA7Z020	N/A	N/A	4	mA
		XQ7Z020	N/A	4	4	mA

Table 5: Typical Quiescent Supply Current (Cont'd)

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
I_{CCINTQ}	PL quiescent V_{CCINT} supply current	XC7Z010	34	34	34	mA
		XC7Z015				mA
		XC7Z020	78	78	78	mA
		XA7Z010	N/A	N/A	34	mA
		XA7Z020	N/A	N/A	78	mA
		XQ7Z020	N/A	78	78	mA
I_{CCAUXQ}	PL quiescent V_{CCAUX} supply current	XC7Z010	18	18	18	mA
		XC7Z015				mA
		XC7Z020	38	38	38	mA
		XA7Z010	N/A	N/A	18	mA
		XA7Z020	N/A	N/A	38	mA
		XQ7Z020	N/A	38	38	mA
I_{CCOQ}	PL quiescent V_{CCO} supply current	XC7Z010	3	3	3	mA
		XC7Z015				mA
		XC7Z020	3	3	3	mA
		XA7Z010	N/A	N/A	3	mA
		XA7Z020	N/A	N/A	3	mA
		XQ7Z020	N/A	3	3	mA
$I_{CCBRAMQ}$	PL quiescent V_{CCBRAM} supply current	XC7Z010	3	3	3	mA
		XC7Z015				mA
		XC7Z020	6	6	6	mA
		XA7Z010	N/A	N/A	3	mA
		XA7Z020	N/A	N/A	6	mA
		XQ7Z020	N/A	6	6	mA

Notes:

1. Typical values are specified at nominal voltage, 85°C junction temperatures (T_j) with single-ended SelectIO resources.
2. Typical values are for blank configured devices with no output current loads, no active input pull-up resistors, all I/O pins are 3-state and floating.
3. The Xilinx Power Estimator (XPE) spreadsheet tool (download at <http://www.xilinx.com/power>) estimates operating current. When the required power-on current exceeds the estimated operating current, XPE can display the power-on current.

PS Power-On/Off Power Supply Sequencing

The recommended power-on sequence is V_{CCPINT} , V_{CCPAUX} , and V_{CCPLL} together, then the PS V_{CCO} supplies (V_{CCO_MIO0} , V_{CCO_MIO1} , and V_{CCO_DDR}) to achieve minimum current draw and ensure that the I/Os are 3-stated at power-on. The recommended power-off sequence is the reverse of the power-on sequence. If V_{CCPAUX} , V_{CCPLL} , and the PS V_{CCO} supplies (V_{CCO_MIO0} , V_{CCO_MIO1} , and V_{CCO_DDR}) have the same recommended voltage levels, then they can be powered by the same supply and ramped simultaneously. Xilinx recommends powering V_{CCPLL} with the same supply as V_{CCPAUX} , with an optional ferrite bead filter.

For V_{CCO_MIO0} and V_{CCO_MIO1} voltages of 3.3V:

- The voltage difference between V_{CCO_MIO0} / V_{CCO_MIO1} and V_{CCPAUX} must not exceed 2.625V for longer than $T_{VCCO2VCCPAUX}$ for each power-on/off cycle to maintain device reliability levels.
- The $T_{VCCO2VCCPAUX}$ time can be allocated in any percentage between the power-on and power-off ramps.

PL Power-On/Off Power Supply Sequencing

The recommended power-on sequence for the PL is V_{CCINT} , V_{CCBRAM} , V_{CCPAUX} , and V_{CCO} to achieve minimum current draw and ensure that the I/Os are 3-stated at power-on. The recommended power-off sequence is the reverse of the power-on sequence. If V_{CCINT} and V_{CCBRAM} have the same recommended voltage levels then both can be powered by the same supply and ramped simultaneously. If V_{CCPAUX} and V_{CCO} have the same recommended voltage levels then both can be powered by the same supply and ramped simultaneously.

For V_{CCO} voltages of 3.3V in HR I/O banks and configuration bank 0:

- The voltage difference between V_{CCO} and V_{CCPAUX} must not exceed 2.625V for longer than $T_{VCCO2VCCPAUX}$ for each power-on/off cycle to maintain device reliability levels.
- The $T_{VCCO2VCCPAUX}$ time can be allocated in any percentage between the power-on and power-off ramps.

GTP Transceivers (XC7Z015 Only)

The recommended power-on sequence to achieve minimum current draw for the GTP transceivers (XC7Z015 only) is V_{CCINT} , $V_{MGTAVCC}$, $V_{MGTAVTT}$ OR $V_{MGTAVCC}$, V_{CCINT} , $V_{MGTAVTT}$. Both $V_{MGTAVCC}$ and V_{CCINT} can be ramped simultaneously. The recommended power-off sequence is the reverse of the power-on sequence to achieve minimum current draw.

If these recommended sequences are not met, current drawn from $V_{MGTAVTT}$ can be higher than specifications during power-up and power-down.

- When $V_{MGTAVTT}$ is powered before $V_{MGTAVCC}$ and $V_{MGTAVTT} - V_{MGTAVCC} > 150$ mV and $V_{MGTAVCC} < 0.7$ V, the $V_{MGTAVTT}$ current draw can increase by 460 mA per transceiver during $V_{MGTAVCC}$ ramp up. The duration of the current draw can be up to $0.3 \times T_{MGTAVCC}$ (ramp time from GND to 90% of $V_{MGTAVCC}$). The reverse is true for power-down.
- When $V_{MGTAVTT}$ is powered before V_{CCINT} and $V_{MGTAVTT} - V_{CCINT} > 150$ mV and $V_{CCINT} < 0.7$ V, the $V_{MGTAVTT}$ current draw can increase by 50 mA per transceiver during V_{CCINT} ramp up. The duration of the current draw can be up to $0.3 \times T_{VCCINT}$ (ramp time from GND to 90% of V_{CCINT}). The reverse is true for power-down.

PS—PL Power Sequencing

The PS and PL power supplies are fully independent. PS power supplies (V_{CCPINT} , V_{CCPAUX} , V_{CCPLL} , V_{CCO_DDR} , V_{CCO_MIO0} , and V_{CCO_MIO1}) can be powered before or after the PL power supplies (V_{CCINT} , V_{CCBRAM} , V_{CCPAUX} , V_{CCO} , $V_{MGTAVCC}$, $V_{MGTAVTT}$, and V_{CCADC}). The PS and PL power regions are isolated to prevent damage.

Power Supply Requirements

Table 6 shows the minimum current, in addition to I_{CCQ} , that is required by Zynq-7000 devices for proper power-on and configuration. If the current minimums shown in Table 5 and Table 6 are met, the device powers on after all four PL supplies have passed through their power-on reset threshold voltages. The Zynq-7000 device must not be configured until after V_{CCINT} is applied. Once initialized and configured, use the Xilinx Power Estimator (XPE) spreadsheet tool (download at www.xilinx.com/power) to estimate current drain on these supplies.

Table 6: Power-On Current for Zynq-7000 Devices

Device	$I_{CCPINTMIN}$	$I_{CCPAUXMIN}$	$I_{CCDDRMIN}$	$I_{CCINTMIN}$	$I_{CCAUXMIN}$	I_{CCOMIN}	$I_{CCBRAMMIN}$	Units
XC7Z010 XA7Z010	$I_{CCPINTQ} + 70$	$I_{CCPAUXQ} + 40$	$I_{CCDDRQ} + 100$ mA per bank	$I_{CCINTQ} + 40$	$I_{CCAUXQ} + 60$	$I_{CCOQ} + 90$ mA per bank	$I_{CCBRAMQ} + 40$	mA
XC7Z015								mA
XC7Z020 XA7Z020 XQ7Z020	$I_{CCPINTQ} + 70$	$I_{CCPAUXQ} + 40$	$I_{CCDDRQ} + 100$ mA per bank	$I_{CCINTQ} + 70$	$I_{CCAUXQ} + 60$	$I_{CCOQ} + 90$ mA per bank	$I_{CCBRAMQ} + 40$	mA

Table 7: Power Supply Ramp Time

Symbol	Description	Conditions	Min	Max	Units
$T_{VCCPINT}$	Ramp time from GND to 90% of V_{CCPINT}		0.2	50	ms
$T_{VCCPAUX}$	Ramp time from GND to 90% of V_{CCPAUX}		0.2	50	ms
T_{VCCO_DDR}	Ramp time from GND to 90% of V_{CCO_DDR}		0.2	50	ms
T_{VCCO_MIO}	Ramp time from GND to 90% of V_{CCO_MIO}		0.2	50	ms
T_{VCCINT}	Ramp time from GND to 90% of V_{CCINT}		0.2	50	ms
T_{VCCO}	Ramp time from GND to 90% of V_{CCO}		0.2	50	ms
T_{VCCAUX}	Ramp time from GND to 90% of V_{CCAUX}		0.2	50	ms
$T_{VCCBRAM}$	Ramp time from GND to 90% of V_{CCBRAM}		0.2	50	ms
$T_{VCCO2VCCAUX}$	Allowed time per power cycle for $V_{CCO} - V_{CCAUX} > 2.625V$ and $V_{CCO_MIO} - V_{CCPAUX} > 2.625V$	$T_j = 125^{\circ}C^{(1)}$	–	300	ms
		$T_j = 100^{\circ}C^{(1)}$	–	500	
		$T_j = 85^{\circ}C^{(1)}$	–	800	
$T_{MGTAVCC}$	Ramp time from GND to 90% of $V_{MGTAVCC}$		0.2	50	ms
$T_{MGTAVTT}$	Ramp time from GND to 90% of $V_{MGTAVTT}$		0.2	50	ms

Notes:

- Based on 240,000 power cycles with nominal V_{CCO} of 3.3V or 36,500 power cycles with worst case V_{CCO} of 3.465V.

DC Input and Output Levels

Values for V_{IL} and V_{IH} are recommended input voltages. Values for I_{OL} and I_{OH} are guaranteed over the recommended operating conditions at the V_{OL} and V_{OH} test points. Only selected standards are tested. These are chosen to ensure that all standards meet their specifications. The selected standards are tested at a minimum V_{CCO} with the respective V_{OL} and V_{OH} voltage levels shown. Other standards are sample tested.

PS I/O Levels

Table 8: PS DC Input and Output Levels⁽¹⁾

Bank	I/O Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
		V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
MIO	LVC MOS18	-0.300	35% V_{CCO_MIO}	65% V_{CCO_MIO}	$V_{CCO_MIO} + 0.300$	0.450	$V_{CCO_MIO} - 0.450$	8	-8
MIO	LVC MOS25	-0.300	0.700	1.700	$V_{CCO_MIO} + 0.300$	0.400	$V_{CCO_MIO} - 0.400$	8	-8
MIO	LVC MOS33	-0.300	0.800	2.000	3.450	0.400	$V_{CCO_MIO} - 0.400$	8	-8
MIO	HSTL_I_18	-0.300	$V_{PREF} - 0.100$	$V_{PREF} + 0.100$	$V_{CCO_MIO} + 0.300$	0.400	$V_{CCO_MIO} - 0.400$	8	-8
DDR	SSTL18_I	-0.300	$V_{PREF} - 0.125$	$V_{PREF} + 0.125$	$V_{CCO_DDR} + 0.300$	$V_{CCO_DDR}/2 - 0.470$	$V_{CCO_DDR}/2 + 0.470$	8	-8
DDR	SSTL15	-0.300	$V_{PREF} - 0.100$	$V_{PREF} + 0.100$	$V_{CCO_DDR} + 0.300$	$V_{CCO_DDR}/2 - 0.175$	$V_{CCO_DDR}/2 + 0.175$	13.0	-13.0
DDR	SSTL135	-0.300	$V_{PREF} - 0.090$	$V_{PREF} + 0.090$	$V_{CCO_DDR} + 0.300$	$V_{CCO_DDR}/2 - 0.150$	$V_{CCO_DDR}/2 + 0.150$	13.0	-13.0
DDR	HSUL_12	-0.300	$V_{PREF} - 0.130$	$V_{PREF} + 0.130$	$V_{CCO_DDR} + 0.300$	20% V_{CCO_DDR}	80% V_{CCO_DDR}	0.1	-0.1

Notes:

1. Tested according to relevant specifications.

Table 9: PS Complementary Differential DC Input and Output Levels

Bank	I/O Standard	$V_{ICM}^{(1)}$			$V_{ID}^{(2)}$		$V_{OL}^{(3)}$	$V_{OH}^{(4)}$	I_{OL}	I_{OH}
		V, Min	V, Typ	V, Max	V, Min	V, Max	V, Max	V, Min	mA, Max	mA, Min
DDR	DIFF_HSUL_12	0.300	0.600	0.850	0.100	—	20% V_{CCO}	80% V_{CCO}	0.100	-0.100
DDR	DIFF_SSTL135	0.300	0.675	1.000	0.100	—	$(V_{CCO_DDR}/2) - 0.150$	$(V_{CCO_DDR}/2) + 0.150$	13.0	-13.0
DDR	DIFF_SSTL15	0.300	0.750	1.125	0.100	—	$(V_{CCO_DDR}/2) - 0.175$	$(V_{CCO_DDR}/2) + 0.175$	13.0	-13.0
DDR	DIFF_SSTL18_I	0.300	0.900	1.425	0.100	—	$(V_{CCO_DDR}/2) - 0.470$	$(V_{CCO_DDR}/2) + 0.470$	8.00	-8.00

Notes:

1. V_{ICM} is the input common mode voltage.
2. V_{ID} is the input differential voltage ($Q-\bar{Q}$).
3. V_{OL} is the single-ended low-output voltage.
4. V_{OH} is the single-ended high-output voltage.

PL I/O Levels

Table 10: SelectIO DC Input and Output Levels⁽¹⁾⁽²⁾

I/O Standard	V _{IL}		V _{IH}		V _{OL}	V _{OH}	I _{OL}	I _{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
HSTL_I	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	8.00	−8.00
HSTL_I_18	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	8.00	−8.00
HSTL_II	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	16.00	−16.00
HSTL_II_18	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	16.00	−16.00
HSUL_12	−0.300	V _{REF} − 0.130	V _{REF} + 0.130	V _{CCO} + 0.300	20% V _{CCO}	80% V _{CCO}	0.10	−0.10
LVC MOS12	−0.300	35% V _{CCO}	65% V _{CCO}	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	Note 3	Note 3
LVC MOS15	−0.300	35% V _{CCO}	65% V _{CCO}	V _{CCO} + 0.300	25% V _{CCO}	75% V _{CCO}	Note 4	Note 4
LVC MOS18	−0.300	35% V _{CCO}	65% V _{CCO}	V _{CCO} + 0.300	0.450	V _{CCO} − 0.450	Note 5	Note 5
LVC MOS25	−0.300	0.7	1.700	V _{CCO} + 0.300	0.400	V _{CCO} − 0.400	Note 4	Note 4
LVC MOS33	−0.300	0.8	2.000	3.450	0.400	V _{CCO} − 0.400	Note 4	Note 4
LVTTL	−0.300	0.8	2.000	3.450	0.400	2.400	Note 5	Note 5
MOBILE_DDR	−0.300	20% V _{CCO}	80% V _{CCO}	V _{CCO} + 0.300	10% V _{CCO}	90% V _{CCO}	0.10	−0.10
PCI33_3	−0.400	30% V _{CCO}	50% V _{CCO}	V _{CCO} + 0.500	10% V _{CCO}	90% V _{CCO}	1.50	−0.50
SSTL135	−0.300	V _{REF} − 0.090	V _{REF} + 0.090	V _{CCO} + 0.300	V _{CCO} /2 − 0.150	V _{CCO} /2 + 0.150	13.00	−13.00
SSTL135_R	−0.300	V _{REF} − 0.090	V _{REF} + 0.090	V _{CCO} + 0.300	V _{CCO} /2 − 0.150	V _{CCO} /2 + 0.150	8.90	−8.90
SSTL15	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	V _{CCO} /2 − 0.175	V _{CCO} /2 + 0.175	13.00	−13.00
SSTL15_R	−0.300	V _{REF} − 0.100	V _{REF} + 0.100	V _{CCO} + 0.300	V _{CCO} /2 − 0.175	V _{CCO} /2 + 0.175	8.90	−8.90
SSTL18_I	−0.300	V _{REF} − 0.125	V _{REF} + 0.125	V _{CCO} + 0.300	V _{CCO} /2 − 0.470	V _{CCO} /2 + 0.470	8.00	−8.00
SSTL18_II	−0.300	V _{REF} − 0.125	V _{REF} + 0.125	V _{CCO} + 0.300	V _{CCO} /2 − 0.600	V _{CCO} /2 + 0.600	13.40	−13.40

Notes:

1. Tested according to relevant specifications.
2. 3.3V and 2.5V standards are only supported in 3.3V I/O banks.
3. Supported drive strengths of 4, 8, or 12 mA in HR I/O banks.
4. Supported drive strengths of 4, 8, 12, or 16 mA in HR I/O banks.
5. Supported drive strengths of 4, 8, 12, 16, or 24 mA in HR I/O banks.
6. For detailed interface specific DC voltage levels, see the *7 Series FPGAs SelectIO Resources User Guide* ([UG471](#)).

Table 11: Differential SelectIO DC Input and Output Levels

I/O Standard	V _{ICM} ⁽¹⁾			V _{ID} ⁽²⁾			V _{OCM} ⁽³⁾			V _{OD} ⁽⁴⁾		
	V, Min	V, Typ	V, Max	V, Min	V, Typ	V, Max	V, Min	V, Typ	V, Max	V, Min	V, Typ	V, Max
BLVDS_25	0.300	1.200	1.425	0.100	—	—	—	1.250	—	Note 5		
MINI_LVDS_25	0.300	1.200	V _{CCAUX}	0.200	0.400	0.600	1.000	1.200	1.400	0.300	0.450	0.600
PPDS_25	0.200	0.900	V _{CCAUX}	0.100	0.250	0.400	0.500	0.950	1.400	0.100	0.250	0.400
RSDS_25	0.300	0.900	1.500	0.100	0.350	0.600	1.000	1.200	1.400	0.100	0.350	0.600
TMDS_33	2.700	2.965	3.230	0.150	0.675	1.200	V _{CCO} −0.405	V _{CCO} −0.300	V _{CCO} −0.190	0.400	0.600	0.800

Notes:

1. V_{ICM} is the input common mode voltage.
2. V_{ID} is the input differential voltage (Q−Q̄).
3. V_{OCM} is the output common mode voltage.
4. V_{OD} is the output differential voltage (Q−Q̄).
5. V_{OD} for BLVDS will vary significantly depending on topology and loading.

Table 12: Complementary Differential SelectIO DC Input and Output Levels

I/O Standard	$V_{ICM}^{(1)}$			$V_{ID}^{(2)}$		$V_{OL}^{(3)}$	$V_{OH}^{(4)}$	I_{OL}	I_{OH}
	V, Min	V, Typ	V, Max	V, Min	V, Max	V, Max	V, Min	mA, Max	mA, Min
DIFF_HSTL_I	0.300	0.750	1.125	0.100	–	0.400	$V_{CCO}-0.400$	8.00	–8.00
DIFF_HSTL_I_18	0.300	0.900	1.425	0.100	–	0.400	$V_{CCO}-0.400$	8.00	–8.00
DIFF_HSTL_II	0.300	0.750	1.125	0.100	–	0.400	$V_{CCO}-0.400$	16.00	–16.00
DIFF_HSTL_II_18	0.300	0.900	1.425	0.100	–	0.400	$V_{CCO}-0.400$	16.00	–16.00
DIFF_HSUL_12	0.300	0.600	0.850	0.100	–	20% V_{CCO}	80% V_{CCO}	0.100	–0.100
DIFF_MOBILE_DDR	0.300	0.900	1.425	0.100	–	10% V_{CCO}	90% V_{CCO}	0.100	–0.100
DIFF_SSTL135	0.300	0.675	1.000	0.100	–	$(V_{CCO}/2) - 0.150$	$(V_{CCO}/2) + 0.150$	13.0	–13.0
DIFF_SSTL135_R	0.300	0.675	1.000	0.100	–	$(V_{CCO}/2) - 0.150$	$(V_{CCO}/2) + 0.150$	8.9	–8.9
DIFF_SSTL15	0.300	0.750	1.125	0.100	–	$(V_{CCO}/2) - 0.175$	$(V_{CCO}/2) + 0.175$	13.0	–13.0
DIFF_SSTL15_R	0.300	0.750	1.125	0.100	–	$(V_{CCO}/2) - 0.175$	$(V_{CCO}/2) + 0.175$	8.9	–8.9
DIFF_SSTL18_I	0.300	0.900	1.425	0.100	–	$(V_{CCO}/2) - 0.470$	$(V_{CCO}/2) + 0.470$	8.00	–8.00
DIFF_SSTL18_II	0.300	0.900	1.425	0.100	–	$(V_{CCO}/2) - 0.600$	$(V_{CCO}/2) + 0.600$	13.4	–13.4

Notes:

- V_{ICM} is the input common mode voltage.
- V_{ID} is the input differential voltage ($Q-\bar{Q}$).
- V_{OL} is the single-ended low-output voltage.
- V_{OH} is the single-ended high-output voltage.

Table 13: LVDS_25 DC Specifications⁽¹⁾

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
V_{CCO}	Supply voltage		2.375	2.5	2.625	V
V_{OH}	Output High voltage for Q and $\bar{Q}$	$R_T = 100\ \Omega$ across Q and $\bar{Q}$ signals	–	–	1.675	V
V_{OL}	Output Low voltage for Q and $\bar{Q}$	$R_T = 100\ \Omega$ across Q and $\bar{Q}$ signals	0.700	–	–	V
V_{ODIFF}	Differential output voltage ($Q - \bar{Q}$), Q = High ($\bar{Q} - Q$), $\bar{Q}$ = High	$R_T = 100\ \Omega$ across Q and $\bar{Q}$ signals	247	350	600	mV
V_{OCM}	Output common-mode voltage	$R_T = 100\ \Omega$ across Q and $\bar{Q}$ signals	1.00	1.25	1.425	V
V_{IDIFF}	Differential input voltage ($Q - \bar{Q}$), Q = High ($\bar{Q} - Q$), $\bar{Q}$ = High		100	350	600	mV
V_{ICM}	Input common-mode voltage		0.3	1.2	1.425	V

Notes:

- Differential inputs for LVDS_25 can be placed in banks with V_{CCO} levels that are different from the required level for outputs. Consult the *7 Series FPGAs SelectIO Resources User Guide (UG471)* for more information.

AC Switching Characteristics

All values represented in this data sheet are based on the speed specifications in the ISE® Design Suite 14.7 and Vivado® Design Suite 2013.3 as outlined in [Table 14](#).

Table 14: Zynq-7000 All Programmable SoC Speed Specification Version By Device

ISE 14.7	Vivado 2013.3	Device
1.08	1.08	XC7Z010 and XC7Z020
N/A	1.08	XC7Z015
1.06	1.06	XA7Z010, XA7Z020, and XQ7Z020

Switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance Product Specification

These specifications are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary Product Specification

These specifications are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production Product Specification

These specifications are released once enough production silicon of a particular device family member has been characterized to provide full correlation between specifications and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

Testing of AC Switching Characteristics

Internal timing parameters are derived from measuring internal test patterns. All AC switching characteristics are representative of worst-case supply voltage and junction temperature conditions.

For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer and back-annotate to the simulation net list. Unless otherwise noted, values apply to all Zynq-7000 devices.

Speed Grade Designations

Since individual family members are produced at different times, the migration from one category to another depends completely on the status of the fabrication process for each device. [Table 15](#) correlates the current status of each Zynq-7000 device on a per speed grade basis.

Table 15: Zynq-7000 Device Speed Grade Designations

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XC7Z010			-3, -2, -1
XC7Z015	-3, -2, -1		
XC7Z020			-3, -2, -1
XA7Z010		-1I, -1Q	
XA7Z020		-1I, -1Q	
XQ7Z020		-2I, -1I, -1Q	

Production Silicon and Software Status

In some cases, a particular family member (and speed grade) is released to production before a speed specification is released with the correct label (Advance, Preliminary, Production). Any labeling discrepancies are corrected in subsequent speed specification releases.

Table 16 lists the production released Zynq-7000 device, speed grade, and the minimum corresponding supported speed specification version and software revisions. The software and speed specifications listed are the minimum releases required for production. All subsequent releases of software and speed specifications are valid.

Table 16: Zynq-7000 Device Production Software and Speed Specification Release

Device	Speed Grade Designations			
	-3	-2	-1C/-1I	-1Q
XC7Z010	ISE tools 14.5 v1.06 and Vivado tools 2013.1 v1.06	ISE tools 14.4 and the 14.4 device pack v1.05		N/A
XC7Z015				N/A
XC7Z020	ISE tools 14.5 v1.06 and Vivado tools 2013.1 v1.06	ISE tools 14.4 and the 14.4 device pack v1.05		N/A
XA7Z010	N/A			
XA7Z020	N/A			
XQ7Z020	N/A			

Notes:

- Blank entries indicate a device and/or speed grade in advance or preliminary status.

PS Performance Characteristics

For further design requirement details, refer to the *Zynq-7000 All Programmable SoC Technical Reference Manual* (UG585).

Table 17: CPU Clock Domains Performance

Symbol	Clock Ratio	Description	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
F _{CPU_6X4X_621_MAX} ⁽¹⁾	6:2:1	Maximum CPU clock frequency	866	766	667	667	MHz
F _{CPU_3X2X_621_MAX}		Maximum CPU_3X clock frequency	433	383	333	333	MHz
F _{CPU_2X_621_MAX}		Maximum CPU_2X clock frequency	288	255	222	222	MHz
F _{CPU_1X_621_MAX}		Maximum CPU_1X clock frequency	144	127	111	111	MHz
F _{CPU_6X4X_421_MAX} ⁽¹⁾	4:2:1	Maximum CPU clock frequency	710	600	533	533	MHz
F _{CPU_3X2X_421_MAX}		Maximum CPU_3X clock frequency	355	300	267	267	MHz
F _{CPU_2X_421_MAX}		Maximum CPU_2X clock frequency	355	300	267	267	MHz
F _{CPU_1X_421_MAX}		Maximum CPU_1X clock frequency	178	150	133	133	MHz

Notes:

- The maximum frequency during BootROM execution is 500 MHz across all speed specifications.

Table 18: PS DDR Clock Domains Performance⁽¹⁾

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
F _{DDR3_MAX}	Maximum DDR3 interface performance	1066	1066	1066	1066	Mb/s
F _{DDR3L_MAX}	Maximum DDR3L interface performance	1066	1066	1066	1066	Mb/s
F _{DDR2_MAX}	Maximum DDR2 interface performance	800	800	800	800	Mb/s
F _{LPDDR2_MAX}	Maximum LPDDR2 interface performance	800	800	800	800	Mb/s

Table 18: PS DDR Clock Domains Performance⁽¹⁾ (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
F _{DDRCLK_2XMAX}	Maximum DDR_2X clock frequency	444	408	355	355	MHz

Notes:

- All performance numbers apply to both internal and external V_{REF} configurations.

Table 19: PS-PL Interface Performance

Symbol	Description	Min	Max	Units
F _{EMIOGEMCLK}	EMIO gigabit Ethernet controller maximum frequency	–	125	MHz
F _{EMIOSDCLK}	EMIO SD controller maximum frequency	–	25	MHz
F _{EMIOSPICLK}	EMIO SPI controller maximum frequency	–	25	MHz
F _{EMIOJTAGCLK}	EMIO JTAG controller maximum frequency	–	20	MHz
F _{EMIOTRACECLK}	EMIO trace controller maximum frequency	–	125	MHz
F _{FTMCLK}	Fabric trace monitor maximum frequency	–	125	MHz
F _{EMIODMACLK}	DMA maximum frequency	–	100	MHz
F _{AXI_MAX}	Maximum AXI interface performance	–	250	MHz

PS Switching Characteristics

Clocks

Table 20: System Reference Clock Input Requirements

Symbol	Description	Min	Typ	Max	Units
T _{JTPSCLK}	PS_CLK RMS clock jitter tolerance	–	–	±0.5	%
T _{DCPSCLK}	PS_CLK duty cycle	40	–	60	%
T _{RFPSCLK}	PS_CLK rise and fall time	–	4	–	ns
F _{PSCLK}	PS_CLK frequency	30	–	60	MHz

Table 21: PS PLL Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T _{LOCK_PSPLL}	PLL maximum lock time	60	60	60	60	μs
F _{PSPLL_MAX}	PLL maximum output frequency	2000	1800	1600	1600	MHz
F _{PSPLL_MIN}	PLL minimum output frequency	780	780	780	780	MHz

Resets

Table 22: PS Reset Requirements

Symbol	Description	Min	Typ	Max	Units
T _{PSPOR}	Required PS_POR_B assertion time ⁽¹⁾	100	–	–	μs
T _{PSRST}	Required PS_SRST_B assertion time	3	–	–	PS_CLK Clock Cycles

Notes:

- PS_POR_B needs to be asserted low until PS supply voltages reach minimum levels.

PS Configuration

Table 23: Processor Configuration Access Port Switching Characteristics

Symbol	Description	Min	Typ	Max	Units
F_{PCAPCK}	Maximum processor configuration access port (PCAP) frequency	–	–	100	MHz

DDR Memory Interfaces

Table 24: DDR3 Interface Switching Characteristics (1066 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	450	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	131	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	288	–	ps
T_{DQSS}	Output clock to DQS skew	–0.11	0.09	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	532	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	637	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.5V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 25: DDR3 Interface Switching Characteristics (800 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	232	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	401	–	ps
T_{DQSS}	Output clock to DQS skew	–0.10	0.06	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	722	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	882	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.5V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 26: DDR3L Interface Switching Characteristics (800 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	321	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	380	–	ps
T_{DQSS}	Output clock to DQS skew	–0.12	0.04	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	636	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	853	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.35V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 27: LPDDR2 Interface Switching Characteristics (800 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	196	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	328	–	ps
T_{DQSS}	Output clock to DQS skew	0.90	1.06	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	202	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	353	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.2V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 28: LPDDR2 Interface Switching Characteristics (400 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	664	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	766	–	ps
T_{DQSS}	Output clock to DQS skew	0.90	1.06	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	731	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	907	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.2V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 29: DDR2 Interface Switching Characteristics (800 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	147	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	376	–	ps
T_{DQSS}	Output clock to DQS skew	–0.07	0.08	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	732	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	938	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.8V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

Table 30: DDR2 Interface Switching Characteristics (400 Mb/s)⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
$T_{DQDS}^{(2)}$	Output DQ to DQS skew	385	–	ps
$T_{DQDH}^{(3)}$	Output DQS to DQ skew	662	–	ps
T_{DQSS}	Output clock to DQS skew	–0.11	0.06	T_{CK}
$T_{CACK}^{(4)}$	Command/address output setup time with respect to CLK	1760	–	ps
$T_{CKCA}^{(5)}$	Command/address output hold time with respect to CLK	1739	–	ps

Notes:

1. Recommended $V_{CCO_DDR} = 1.8V \pm 5\%$.
2. Measurement is taken from either the rising edge of DQ that crosses $V_{IH}(AC)$ or the falling edge of DQ that crosses $V_{IL}(AC)$ to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses $V_{IL}(DC)$ or the falling edge of DQ that crosses $V_{IH}(DC)$ to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IH}(AC)$ or the falling edge of CMD/ADDR that crosses $V_{IL}(AC)$ to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses $V_{IL}(DC)$ or the falling edge of CMD/ADDR that crosses $V_{IH}(DC)$ to V_{REF} of CLK.

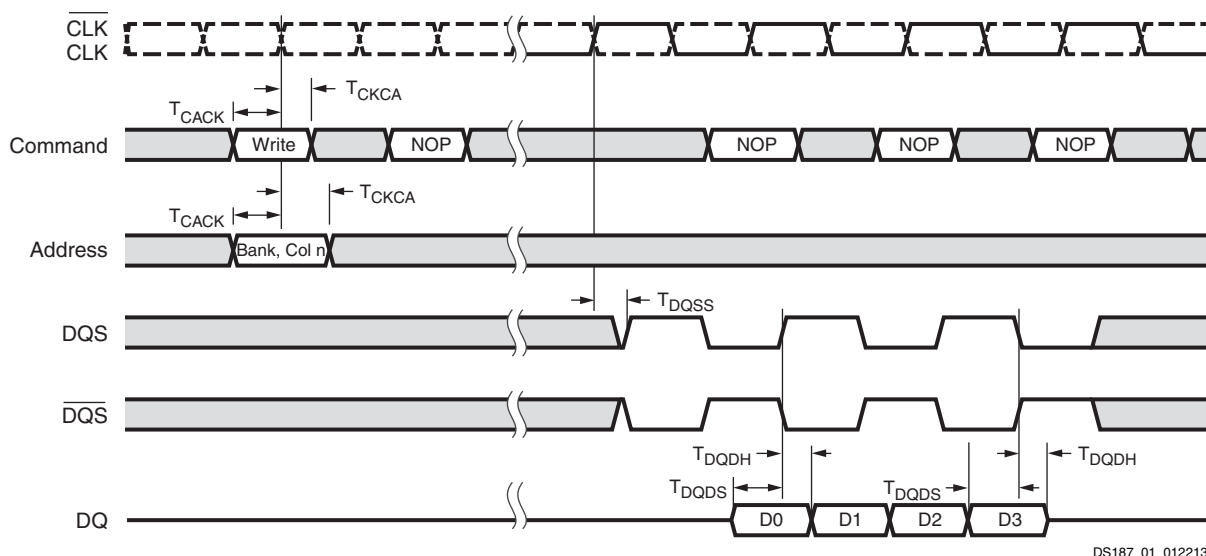


Figure 1: DDR Output Timing Diagram

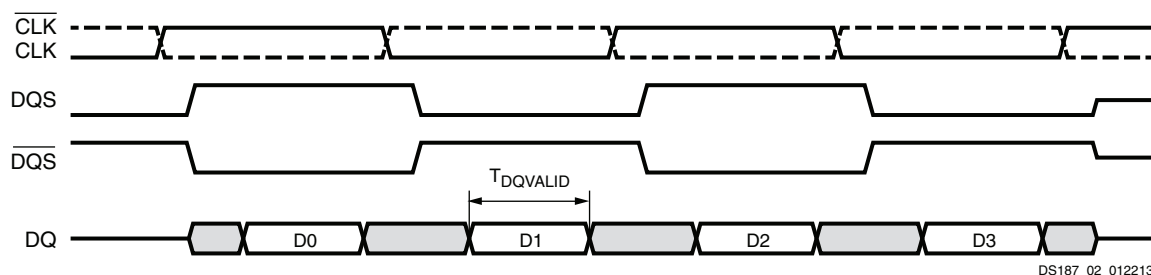


Figure 2: DDR Input Timing Diagram

Static Memory Controller

Table 31: SMC Interface Delay Characteristics⁽¹⁾⁽²⁾

Symbol	Description	Min	Max	Units
T _{NANDDOUT}	NAND_IO output delay from last register to pad	4.12	6.45	ns
T _{NANDALE}	NAND_ALE output delay from last register to pad	5.08	6.33	ns
T _{NANDCLE}	NAND_CLE output delay from last register to pad	4.87	6.40	ns
T _{NANDWE}	NAND_WE_B output delay from last register to pad	4.69	5.89	ns
T _{NANDRE}	NAND_RE_B output delay from last register to pad	5.12	6.44	ns
T _{NANDCE}	NAND_CE_B output delay from last register to pad	4.68	5.89	ns
T _{NANDDIN}	NAND_IO setup time and input delay from pad to first register	1.48	3.09	ns
T _{NANDBUSY}	NAND_BUSY setup time and input delay from pad to first register	2.48	3.33	ns
T _{SRAMA}	SRAM_A output delay from last register to pad	3.94	5.73	ns
T _{SRAMDOUT}	SRAM_DQ output delay from last register to pad	4.66	6.45	ns
T _{SRAMCE}	SRAM_CE output delay from last register to pad	4.57	5.95	ns
T _{SRAMOE}	SRAM_OE_B output delay from last register to pad	4.79	6.13	ns
T _{SRAMBLS}	SRAM_BLS_B output delay from last register to pad	5.25	6.74	ns
T _{SRAMWE}	SRAM_WE_B output delay from last register to pad	5.12	6.48	ns
T _{SRAMDIN}	SRAM_DQ setup time and input delay from pad to first register	1.93	3.05	ns
T _{SRAMWAIT}	SRAM_WAIT setup time and input delay from pad to first register	2.26	3.15	ns

Notes:

1. All parameters do not include the package flight time and register controlled delays.
2. Refer to the ARM® PrimeCell® Static Memory Controller (PL350 series) Technical Reference Manual for more SMC timing details.

Quad-SPI Interfaces

Table 32: Quad-SPI Interface Switching Characteristics

Symbol	Description	Load Conditions	Min	Max	Units
Feedback Clock Enabled					
T _{DCQSPICLK1}	Quad-SPI clock duty cycle	All ⁽¹⁾⁽²⁾	44	56	%
T _{QSPICKO1}	Data and slave select output delay	15 pF ⁽¹⁾	−0.10 ⁽³⁾	2.30	ns
		30 pF ⁽²⁾	−1.00	3.80	
T _{QSPIDCK1}	Input data setup time	15 pF ⁽¹⁾	2.00	−	ns
		30 pF ⁽²⁾	3.30	−	
T _{QSPICKD1}	Input data hold time	15 pF ⁽¹⁾	1.30	−	ns
		30 pF ⁽²⁾	1.50	−	
T _{QSPISSCLK1}	Slave select asserted to next clock edge	All ⁽¹⁾⁽²⁾	1	−	F _{QSPI_REF_CLK} cycle
T _{QSPICLKSS1}	Clock edge to slave select deasserted	All ⁽¹⁾⁽²⁾	1	−	F _{QSPI_REF_CLK} cycle
F _{QSPICLK1}	Quad-SPI device clock frequency	15 pF ⁽¹⁾	−	100 ⁽⁴⁾	MHz
		30 pF ⁽²⁾	−	70 ⁽⁴⁾	
Feedback Clock Disabled					
T _{DCQSPICLK2}	Quad-SPI clock duty cycle	All ⁽¹⁾⁽²⁾	44	56	%
T _{QSPICKO2}	Data and slave select output delay	15 pF ⁽¹⁾	−0.10	3.80	ns
		30 pF ⁽²⁾	−1.00	3.80	ns
T _{QSPIDCK2}	Input data setup time ⁽⁵⁾	All ⁽¹⁾⁽²⁾	$11 - \frac{1}{F_{QSPI_REF_CLK}}$	−	ns
T _{QSPICKD2}	Input data hold time	All ⁽¹⁾⁽²⁾	$\frac{1}{2 \times F_{QSPICLK2}}$	−	ns
T _{QSPISSCLK2}	Slave select asserted to next clock edge	All ⁽¹⁾⁽²⁾	1	−	F _{QSPI_REF_CLK} cycle
T _{QSPICLKSS2}	Clock edge to slave select deasserted	All ⁽¹⁾⁽²⁾	1	−	F _{QSPI_REF_CLK} cycle
F _{QSPICLK2}	Quad-SPI device clock frequency	All ⁽¹⁾⁽²⁾	−	40	MHz
Feedback Clock Enabled or Disabled					
F _{QSPI_REF_CLK}	Quad-SPI reference clock frequency	All ⁽¹⁾⁽²⁾	−	200	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads, feedback clock pin has no load. Quad-SPI single slave select 4-bit I/O mode.
- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 30 pF loads in 4-bit stacked I/O configuration, feedback clock pin has no load. Quad-SPI single slave select 4-bit I/O mode.
- The $T_{QSPICKO1}$ is an effective value. Use it to compute the available memory device input setup and hold timing budgets based on the given device clock-out duty-cycle limits.
- Requires appropriate component selection/board design.
- Use 0 ns as the input data setup time when the calculated $T_{QSPIDCK2}$ value is negative.

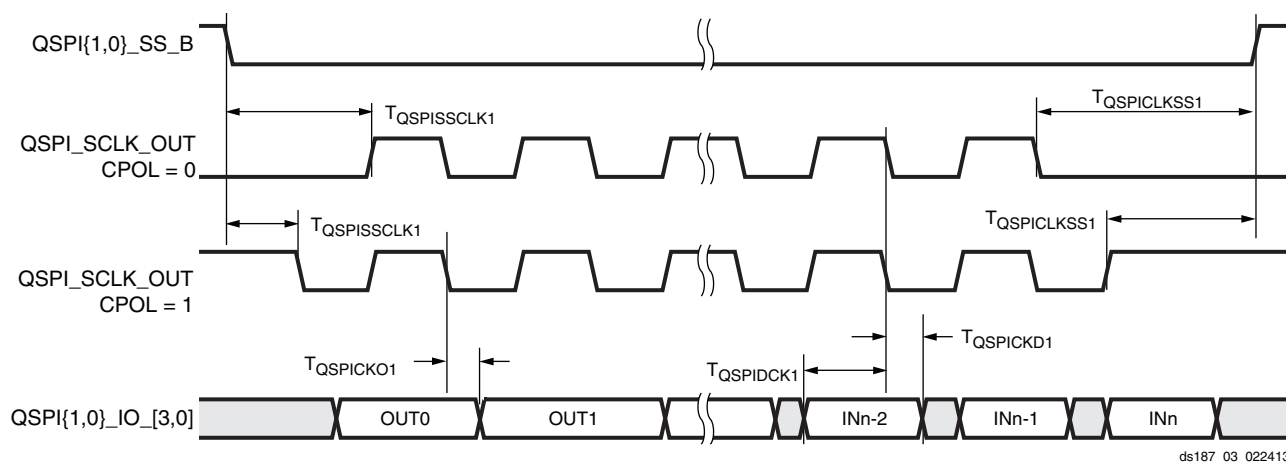


Figure 3: Quad-SPI Interface (Feedback Clock Enabled) Timing Diagram

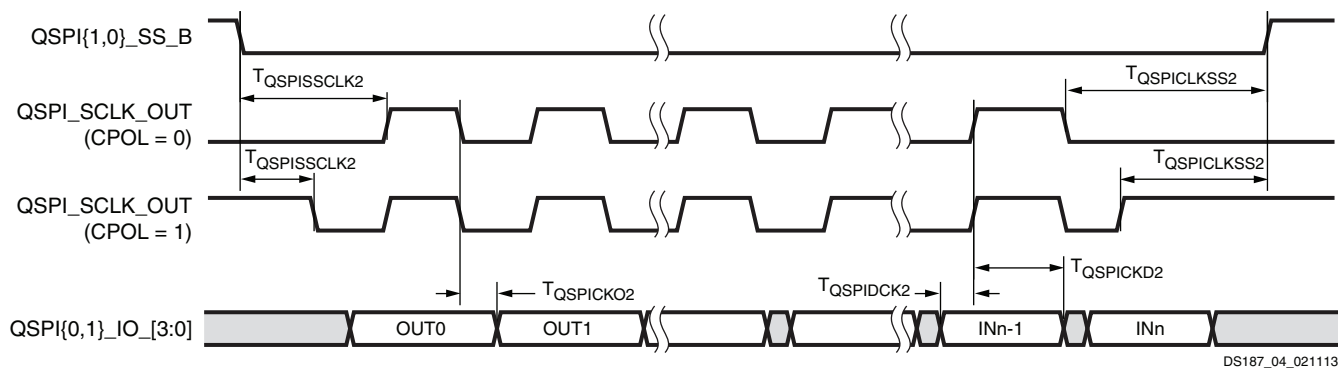


Figure 4: Quad-SPI Interface (Feedback Clock Disabled) Timing Diagram

ULPI Interfaces

Table 33: ULPI Interface Clock Receiving Mode Switching Characteristics⁽¹⁾⁽²⁾

Symbol	Description	Min	Typ	Max	Units
$T_{ULPIDCK}$	Input setup to ULPI clock, all inputs	3.00	–	–	ns
$T_{ULPICKD}$	Input hold to ULPI clock, all inputs	1.00	–	–	ns
$T_{ULPICKO}$	ULPI clock to output valid, all outputs	1.70	–	8.86	ns
$F_{ULPICKLK}$	ULPI device clock frequency	–	60	–	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads, 60 MHz device clock frequency.
2. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

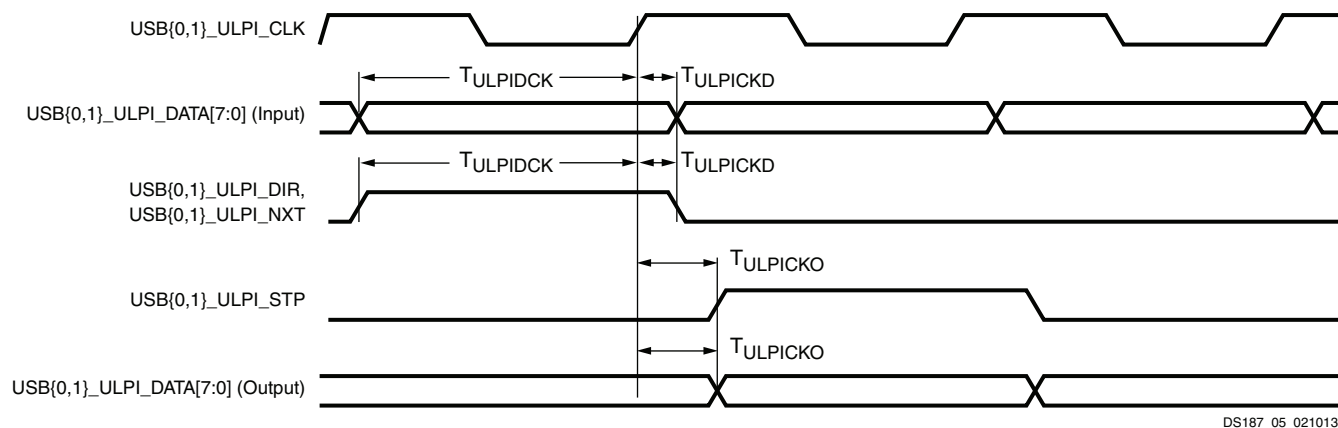


Figure 5: ULPI Interface Timing Diagram

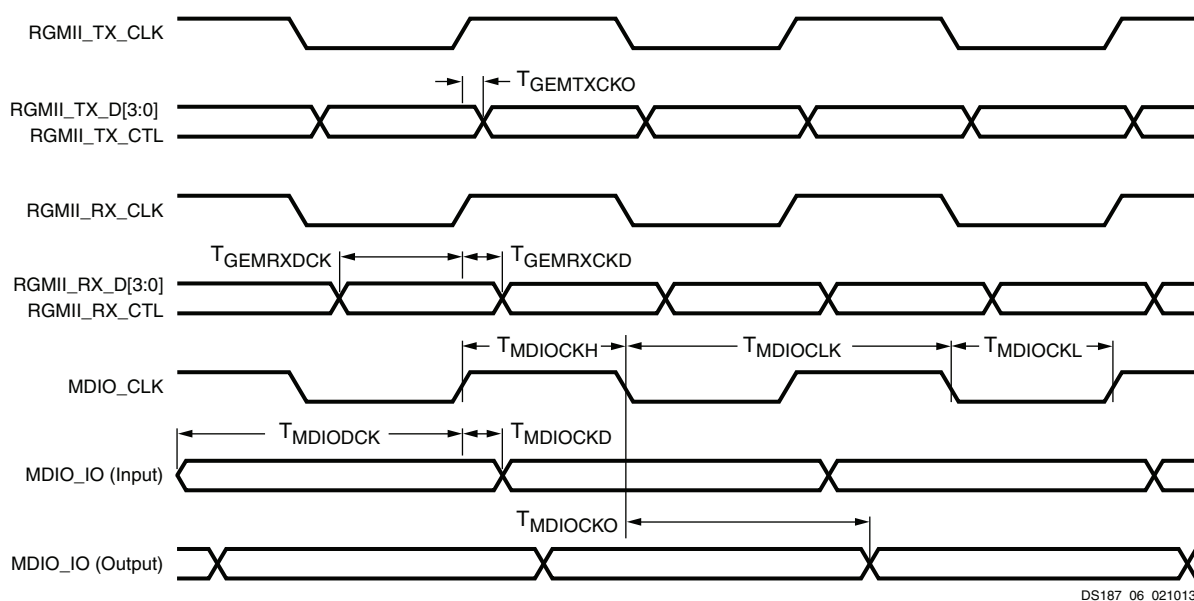
RGMII and MDIO Interfaces

Table 34: RGMII and MDIO Interface Switching Characteristics⁽¹⁾⁽²⁾⁽³⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCGETXCLK}$	Transmit clock duty cycle	45	–	55	%
$T_{GEMTXCKO}$	RGMII_TX_D[3:0], RGMII_TX_CTL output clock to out time	–0.50	–	0.50	ns
$T_{GEMRXDCK}$	RGMII_RX_D[3:0], RGMII_RX_CTL input setup time	0.80	–	–	ns
$T_{GEMRXCKD}$	RGMII_RX_D[3:0], RGMII_RX_CTL input hold time	0.80	–	–	ns
$T_{MDIOCLK}$	MDC output clock period	400	–	–	ns
$T_{MDIOCKH}$	MDC clock High time	160	–	–	ns
$T_{MDIOCKL}$	MDC clock Low time	160	–	–	ns
$T_{MDIODCK}$	MDIO input data setup time	80	–	–	ns
$T_{MDIOCKD}$	MDIO input data hold time	0	–	–	ns
$T_{MDIOCKO}$	MDIO data output delay	–20	–	170	ns
$F_{GETXCLK}$	RGMII_TX_CLK transmit clock frequency	–	125	–	MHz
$F_{GERXCLK}$	RGMII_RX_CLK receive clock frequency	–	125	–	MHz
$F_{ENET_REF_CLK}$	Ethernet reference clock frequency	–	125	–	MHz

Notes:

1. Test conditions: LVCMOS25, fast slew rate, 8 mA drive strength, 15 pF loads. Values in this table are specified during 1000 Mb/s operation.
2. LVCMOS25 slow slew rate and LVCMOS33 are not supported.
3. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.



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Figure 6: RGMII Interface Timing Diagram

SD/SDIO Interfaces

Table 35: SD/SDIO Interface High Speed Mode Switching Characteristics⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCSDHCLK}$	SD device clock duty cycle	—	50	—	%
$T_{SDHSCKO}$	Clock to output delay, all outputs	2.00	—	12.00	ns
$T_{SDHSDCK}$	Input setup time, all inputs	3.00	—	—	ns
$T_{SDHSDCKD}$	Input hold time, all inputs	1.05	—	—	ns
$F_{SD_REF_CLK}$	SD reference clock frequency	—	—	125	MHz
F_{SDHCLK}	High speed mode SD device clock frequency	0	—	50	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

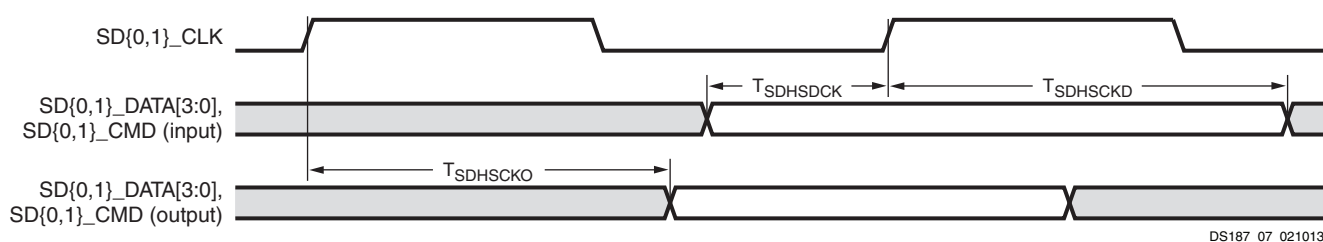


Figure 7: SD/SDIO Interface High Speed Mode Timing Diagram

Table 36: SD/SDIO Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCSDSCLK}$	SD device clock duty cycle	—	50	—	%
T_{SDSCKO}	Clock to output delay, all outputs	2.00	—	12.00	ns
T_{SDSDCK}	Input setup time, all inputs	4.00	—	—	ns
$T_{SDSDCKD}$	Input hold time, all inputs	3.00	—	—	ns
$F_{SD_REF_CLK}$	SD reference clock frequency	—	—	125	MHz
$F_{SDIDCLK}$	Clock frequency in identification mode	—	—	400	KHz
F_{SDSCLK}	Standard mode SD device clock frequency	0	—	25	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

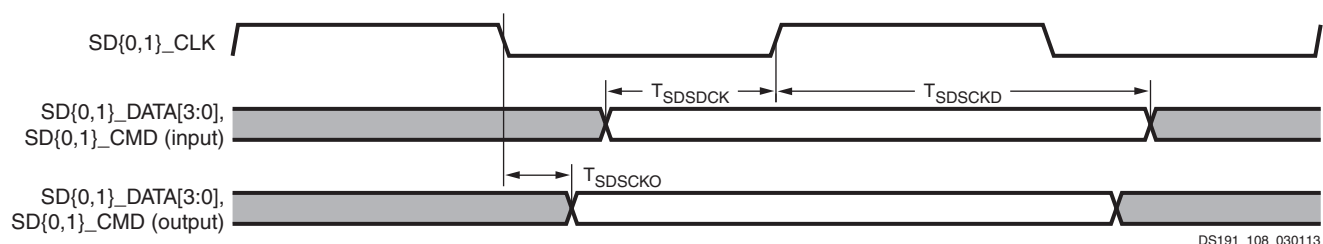


Figure 8: SD/SDIO Interface Standard Mode Timing Diagram

I2C Interfaces

Table 37: I2C Fast Mode Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCI2CFCLK}$	I2C{0,1}SCL duty cycle	–	50	–	%
$T_{I2CFCKO}$	I2C{0,1}SDAO clock to out delay	–	–	900	ns
$T_{I2CFDCK}$	I2C{0,1}SDAI setup time	100	–	–	ns
$F_{I2CFCLK}$	I2C{0,1}SCL clock frequency	–	–	400	KHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

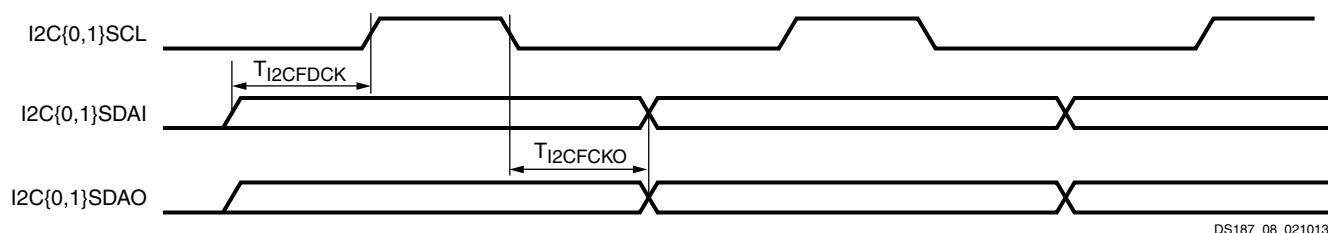


Figure 9: I2C Fast Mode Interface Timing Diagram

Table 38: I2C Standard Mode Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCI2CSCLK}$	I2C{0,1}SCL duty cycle	–	50	–	%
$T_{I2CSCKO}$	I2C{0,1}SDAO clock to out delay	–	–	3450	ns
$T_{I2CSDCK}$	I2C{0,1}SDAI setup time	250	–	–	ns
$F_{I2CSCLK}$	I2C{0,1}SCL clock frequency	–	–	100	KHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

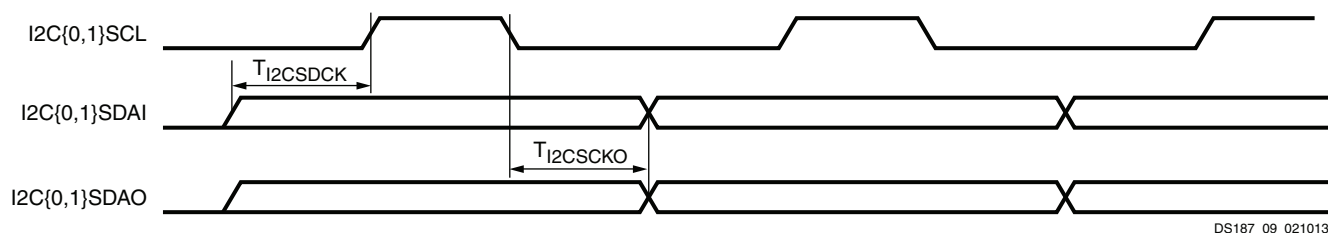


Figure 10: I2C Standard Mode Interface Timing Diagram

SPI Interfaces

Table 39: SPI Master Mode Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
$T_{DCMSPICLK}$	SPI master mode clock duty cycle	—	50	—	%
$T_{MSPIDCK}$	Input setup time for SPI{0,1}_MISO	2.00	—	—	ns
$T_{MSPICKD}$	Input hold time for SPI{0,1}_MISO	8.20	—	—	ns
$T_{MSPICKO}$	Output delay for SPI{0,1}_MOSI and SPI{0,1}_SS	−3.10	—	3.90	ns
$T_{MSPISSCLK}$	Slave select asserted to first active clock edge	1	—	—	$F_{SPI_REF_CLK}$ cycles
$T_{MSPICKSS}$	Last active clock edge to slave select deasserted	0.5	—	—	$F_{SPI_REF_CLK}$ cycles
$F_{MSPICLK}$	SPI master mode device clock frequency	—	—	50.00	MHz
$F_{SPI_REF_CLK}$	SPI reference clock frequency	—	—	200.00	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

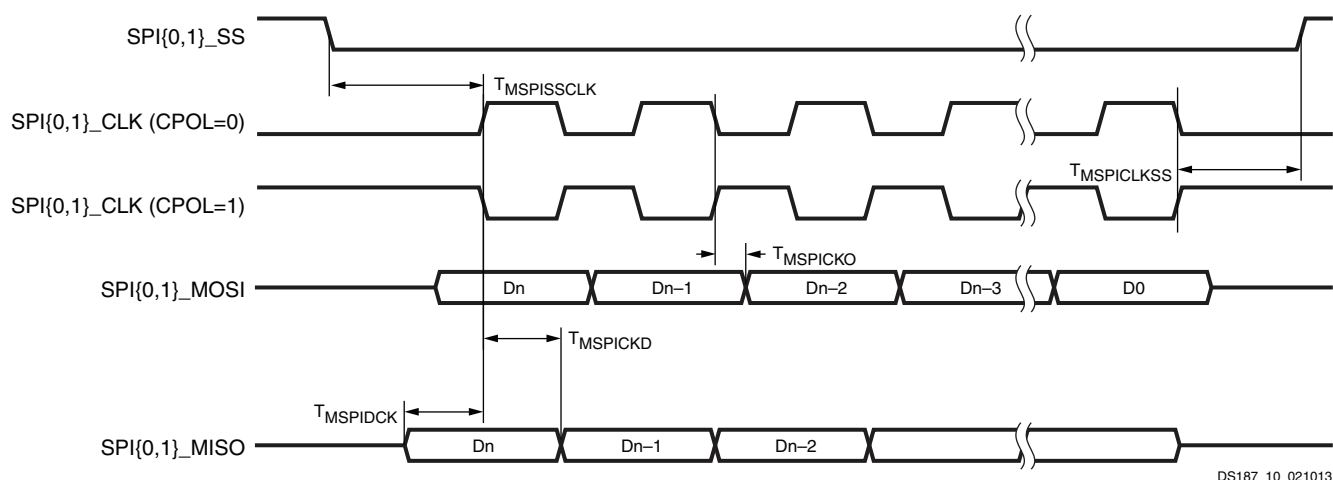


Figure 11: SPI Master (CPHA = 0) Interface Timing Diagram

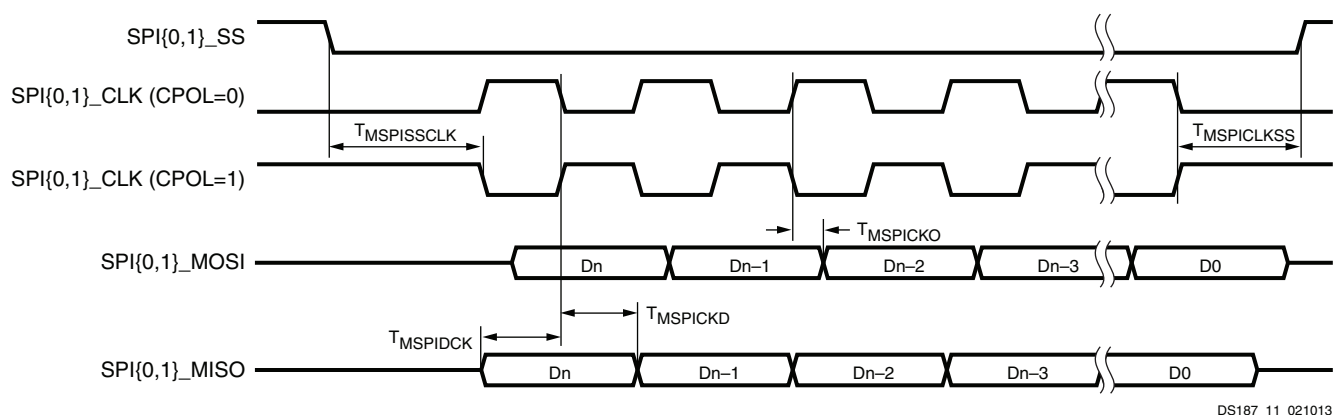


Figure 12: SPI Master (CPHA = 1) Interface Timing Diagram

Table 40: SPI Slave Mode Interface Switching Characteristics⁽¹⁾⁽²⁾

Symbol	Description	Min	Max	Units
$T_{SSPIDCK}$	Input setup time for SPI{0,1}_MOSI and SPI{0,1}_SS	1	–	$F_{SPI_REF_CLK}$ cycles
$T_{SSPICKD}$	Input hold time for SPI{0,1}_MOSI and SPI{0,1}_SS	1	–	$F_{SPI_REF_CLK}$ cycles
$T_{SSPICKO}$	Output delay for SPI{0,1}_MISO	0	2.6	$F_{SPI_REF_CLK}$ cycles
$T_{SSPISCLK}$	Slave select asserted to first active clock edge	1	–	$F_{SPI_REF_CLK}$ cycles
$T_{SSPICKSS}$	Last active clock edge to slave select deasserted	1	–	$F_{SPI_REF_CLK}$ cycles
$F_{SSPICKLK}$	SPI slave mode device clock frequency	–	25	MHz
$F_{SPI_REF_CLK}$	SPI reference clock frequency	–	200	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.
2. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

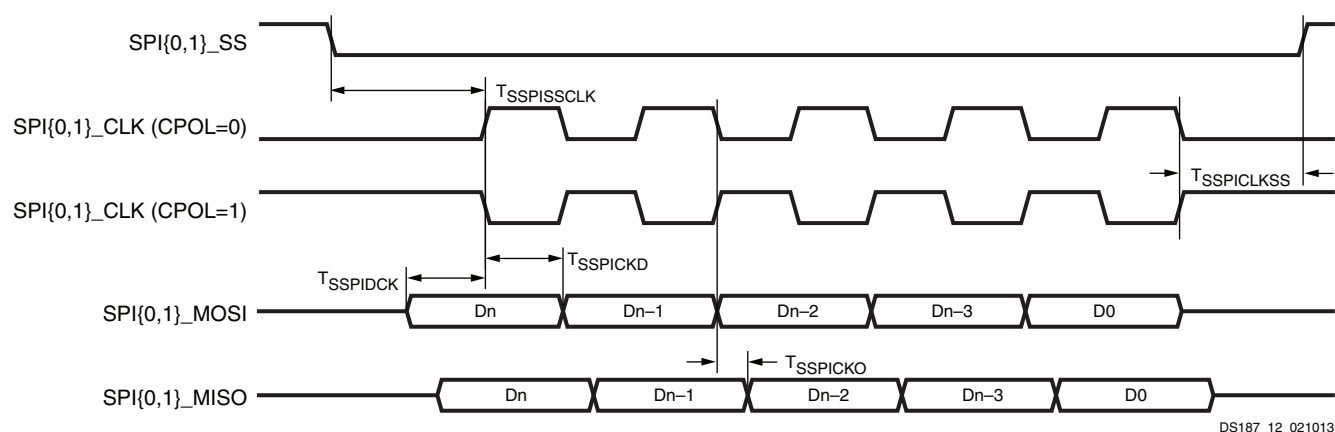


Figure 13: SPI Slave (CPHA = 0) Interface Timing Diagram

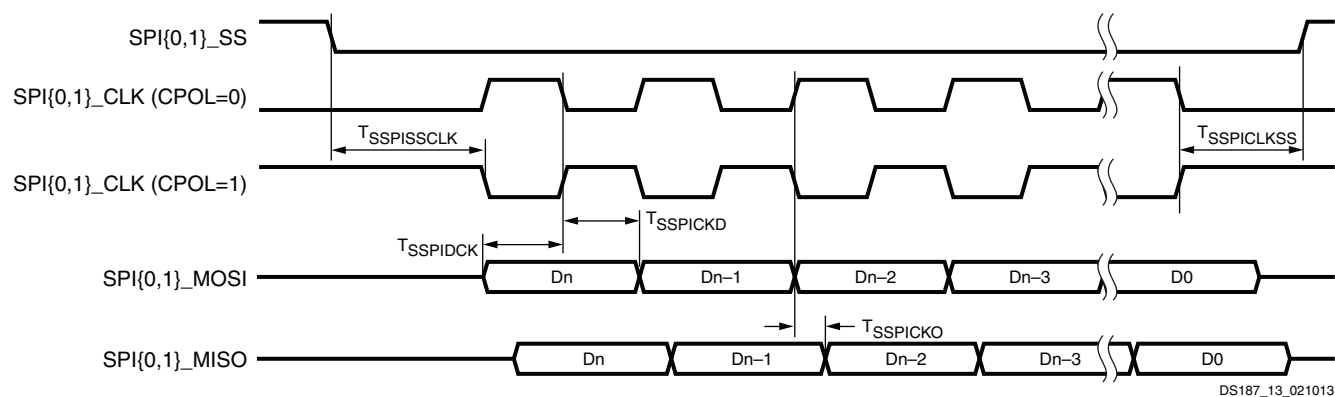


Figure 14: SPI Slave (CPHA = 1) Interface Timing Diagram

CAN Interfaces

Table 41: CAN Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{PWCANRX}$	Minimum receive pulse width	1	–	μ s
$T_{PWCANTX}$	Minimum transmit pulse width	1	–	μ s
$F_{CAN_REF_CLK}$	Internally sourced CAN reference clock frequency	–	100	MHz
	Externally sourced CAN reference clock frequency	–	40	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

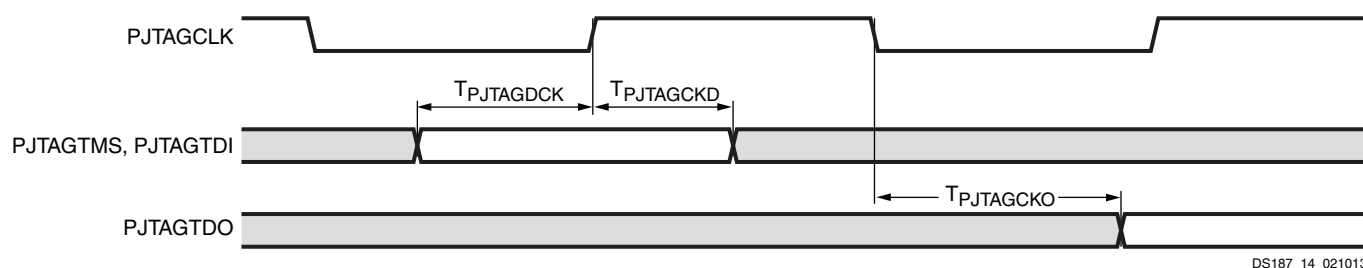
PJTAG Interfaces

Table 42: PJTAG Interface⁽¹⁾⁽²⁾

Symbol	Description	Min	Max	Units
$T_{PJTAGDCK}$	PJTAG input setup time	2.4	–	ns
$T_{PJTAGCKD}$	PJTAG input hold time	2.0	–	ns
$T_{PJTAGCKO}$	PJTAG clock to out delay	–	12.5	ns
$T_{PJTAGCLK}$	PJTAG clock frequency	–	20	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.
- All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.



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Figure 15: PJTAG Interface Timing Diagram

UART Interfaces

Table 43: UART Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
$BAUD_{TXMAX}$	Maximum transmit baud rate	–	1	Mb/s
$BAUD_{RXMAX}$	Maximum receive baud rate	–	1	Mb/s
$F_{UART_REF_CLK}$	UART reference clock frequency	–	100	MHz

Notes:

- Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

GPIO Interfaces

Table 44: GPIO Banks Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{PWGPIOH}$	Input high pulse width	$10 \times 1/\text{cpu1x}$	—	μs
$T_{PWGPIOL}$	Input low pulse width	$10 \times 1/\text{cpu1x}$	—	μs

Notes:

1. Pulse width requirement for interrupt.

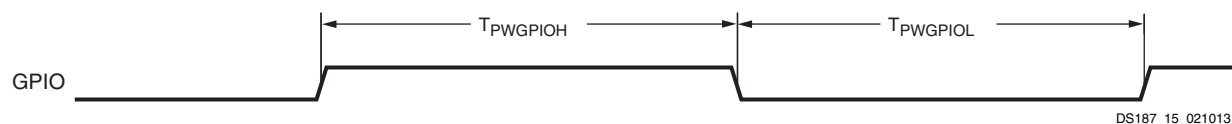


Figure 16: GPIO Interface Timing Diagram

Trace Interface

Table 45: Trace Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
T_{TCECKO}	Trace clock to output delay, all outputs	–1.4	1.5	ns
$T_{DCTCECLK}$	Trace clock duty cycle	40	60	%
F_{TCECLK}	Trace clock frequency	—	80	MHz

Notes:

1. Test conditions: LVCMOS25, fast slew rate, 8 mA drive strength, 15 pF loads.

Triple Timer Counter Interface

Table 46: Triple Timer Counter interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
$T_{PWTTCOCLK}$	Triple timer counter output clock pulse width	$2 \times 1/\text{cpu1x}$	—	ns
$F_{TTCOCLK}$	Triple timer counter output clock frequency	—	$\text{cpu1x}/4$	MHz
$T_{TTCICLKH}$	Triple timer counter input clock high pulse width	$1.5 \times 1/\text{cpu1x}$	—	ns
$T_{TTCICLKL}$	Triple timer counter input clock low pulse width	$1.5 \times 1/\text{cpu1x}$	—	ns
$F_{TTCICLK}$	Triple timer counter input clock frequency	—	$\text{cpu1x}/3$	MHz

Notes:

1. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

Watchdog Timer

Table 47: Watchdog Timer Switching Characteristics

Symbol	Description	Min	Max	Units
F_{WDTCLK}	Watchdog timer input clock frequency	—	10	MHz

PL Performance Characteristics

This section provides the performance characteristics of some common functions and designs implemented in the PL. The numbers reported here are worst-case values; they have all been fully characterized. These values are subject to the same guidelines as the [AC Switching Characteristics, page 12](#).

Table 48: PL Networking Applications Interface Performances

Description	Speed Grade				Units
	-3	-2	-1C/-1I	-1Q	
SDR LVDS transmitter (using OSERDES; DATA_WIDTH = 4 to 8)	680	680	600	600	Mb/s
DDR LVDS transmitter (using OSERDES; DATA_WIDTH = 4 to 14)	1250	1250	950	950	Mb/s
SDR LVDS receiver (SFI-4.1) ⁽¹⁾	680	680	600	600	Mb/s
DDR LVDS receiver (SPI-4.2) ⁽¹⁾	1250	1250	950	950	Mb/s

Notes:

1. LVDS receivers are typically bounded with certain applications where specific dynamic phase-alignment (DPA) algorithms dominate deterministic performance.

Table 49: Maximum Physical Interface (PHY) Rate for Memory Interfaces IP available with the Memory Interface Generator⁽¹⁾⁽²⁾

Memory Standard	Speed Grade				Units
	-3	-2	-1C/-1I	-1Q	
4:1 Memory Controllers					
DDR3	1066 ⁽³⁾	800	800	667	Mb/s
DDR3L	800	800	667	N/A	Mb/s
DDR2	800	800	667	533	Mb/s
LPDDR2	667	667	533	400	Mb/s
2:1 Memory Controllers					
DDR3	800	700	620	620	Mb/s
DDR3L	800	700	620	N/A	Mb/s
DDR2	800	700	620	533	Mb/s

Notes:

1. V_{REF} tracking is required. For more information, see the *7 Series FPGAs Memory Interface Solutions User Guide* ([UG586](#)).
2. When using the internal V_{REF} the maximum data rate is 800 Mb/s (400 MHz).
3. The maximum PHY rate is 800 Mb/s in bank 13 of the XC7Z015, XC7Z020, XA7Z020, and XQ7Z020 devices.

PL Switching Characteristics

IOB Pad Input/Output/3-State

Table 50 summarizes the values of standard-specific data input delay adjustments, output delays terminating at pads (based on standard), and 3-state delays.

- T_{IOPI} is described as the delay from IOB pad through the input buffer to the I-pin of an IOB pad. The delay varies depending on the capability of the SelectIO input buffer.
- T_{IOOP} is described as the delay from the O pin to the IOB pad through the output buffer of an IOB pad. The delay varies depending on the capability of the SelectIO output buffer.
- T_{IOTP} is described as the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is disabled. The delay varies depending on the SelectIO capability of the output buffer. In HR I/O banks, the IN_TERM termination turn-on time is always faster than T_{IOTP} when the INTERMDISABLE pin is used.

Table 50: 3.3V IOB High Range (HR) Switching Characteristics

I/O Standard	T _{IOPI}				T _{IOOP}				T _{IOTP}				Units
	Speed Grade				Speed Grade				Speed Grade				
	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	
LVTTTL_S4	1.26	1.34	1.41	1.53	3.80	3.93	4.18	4.18	4.37	4.59	5.01	5.01	ns
LVTTTL_S8	1.26	1.34	1.41	1.53	3.54	3.66	3.92	3.92	4.11	4.32	4.75	4.75	ns
LVTTTL_S12	1.26	1.34	1.41	1.53	3.52	3.65	3.90	3.90	4.09	4.31	4.73	4.73	ns
LVTTTL_S16	1.26	1.34	1.41	1.53	3.07	3.19	3.45	3.45	3.64	3.85	4.28	4.28	ns
LVTTTL_S24	1.26	1.34	1.41	1.53	3.29	3.41	3.67	3.67	3.86	4.07	4.50	4.50	ns
LVTTTL_F4	1.26	1.34	1.41	1.53	3.26	3.38	3.64	3.64	3.83	4.04	4.46	4.46	ns
LVTTTL_F8	1.26	1.34	1.41	1.53	2.74	2.87	3.12	3.12	3.31	3.52	3.95	3.95	ns
LVTTTL_F12	1.26	1.34	1.41	1.53	2.73	2.85	3.10	3.10	3.29	3.51	3.93	3.93	ns
LVTTTL_F16	1.26	1.34	1.41	1.53	2.56	2.68	2.93	2.93	3.12	3.34	3.76	3.76	ns
LVTTTL_F24	1.26	1.34	1.41	1.53	2.52	2.65	2.90	3.23	3.09	3.31	3.73	4.06	ns
LVDS_25	0.73	0.81	0.88	0.89	1.29	1.41	1.67	1.67	1.86	2.07	2.49	2.49	ns
MINI_LVDS_25	0.73	0.81	0.88	0.89	1.27	1.40	1.65	1.65	1.84	2.06	2.48	2.48	ns
BLVDS_25	0.73	0.81	0.88	0.88	1.84	1.96	2.21	2.76	2.40	2.62	3.04	3.59	ns
RSDS_25 (point to point)	0.73	0.81	0.88	0.89	1.27	1.40	1.65	1.65	1.84	2.06	2.48	2.48	ns
PPDS_25	0.73	0.81	0.88	0.89	1.29	1.41	1.67	1.67	1.86	2.07	2.49	2.49	ns
TMDS_33	0.73	0.81	0.88	0.92	1.41	1.54	1.79	1.79	1.98	2.20	2.62	2.62	ns
PCI33_3	1.24	1.32	1.39	1.52	3.10	3.22	3.48	3.48	3.67	3.88	4.31	4.31	ns
HSUL_12	0.67	0.75	0.82	0.88	1.81	1.93	2.18	2.18	2.37	2.59	3.01	3.01	ns
DIFF_HSUL_12	0.68	0.76	0.83	0.86	1.81	1.93	2.18	2.18	2.37	2.59	3.01	3.01	ns
HSTL_I_S	0.67	0.75	0.82	0.86	1.62	1.74	1.99	1.99	2.19	2.40	2.82	2.82	ns
HSTL_II_S	0.65	0.73	0.80	0.86	1.41	1.54	1.79	1.79	1.98	2.20	2.62	2.62	ns
HSTL_I_18_S	0.67	0.75	0.82	0.88	1.29	1.41	1.67	1.67	1.86	2.07	2.49	2.49	ns
HSTL_II_18_S	0.66	0.75	0.81	0.88	1.41	1.54	1.79	1.79	1.98	2.20	2.62	2.62	ns
DIFF_HSTL_I_S	0.68	0.76	0.83	0.86	1.59	1.71	1.96	1.96	2.15	2.37	2.79	2.79	ns
DIFF_HSTL_II_S	0.68	0.76	0.83	0.86	1.51	1.63	1.88	1.88	2.08	2.29	2.71	2.71	ns
DIFF_HSTL_I_18_S	0.71	0.79	0.86	0.86	1.38	1.51	1.76	1.76	1.95	2.17	2.59	2.59	ns
DIFF_HSTL_II_18_S	0.70	0.78	0.85	0.88	1.46	1.58	1.84	1.84	2.03	2.24	2.67	2.67	ns

Table 50: 3.3V IOB High Range (HR) Switching Characteristics (Cont'd)

I/O Standard	T _{IOPI}				T _{IOOP}				T _{IOTP}				Units
	Speed Grade				Speed Grade				Speed Grade				
	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	
HSTL_I_F	0.67	0.75	0.82	0.86	1.10	1.22	1.48	1.49	1.67	1.88	2.31	2.32	ns
HSTL_II_F	0.65	0.73	0.80	0.86	1.12	1.24	1.49	1.49	1.69	1.90	2.32	2.32	ns
HSTL_I_18_F	0.67	0.75	0.82	0.88	1.13	1.26	1.51	1.54	1.70	1.92	2.34	2.37	ns
HSTL_II_18_F	0.66	0.75	0.81	0.88	1.12	1.24	1.49	1.51	1.69	1.90	2.32	2.34	ns
DIFF_HSTL_I_F	0.68	0.76	0.83	0.86	1.18	1.30	1.56	1.56	1.75	1.96	2.39	2.39	ns
DIFF_HSTL_II_F	0.68	0.76	0.83	0.86	1.21	1.33	1.59	1.59	1.78	1.99	2.42	2.42	ns
DIFF_HSTL_I_18_F	0.71	0.79	0.86	0.86	1.21	1.33	1.59	1.59	1.78	1.99	2.42	2.42	ns
DIFF_HSTL_II_18_F	0.70	0.78	0.85	0.88	1.21	1.33	1.59	1.59	1.78	1.99	2.42	2.42	ns
LVC MOS33_S4	1.26	1.34	1.41	1.52	3.80	3.93	4.18	4.18	4.37	4.59	5.01	5.01	ns
LVC MOS33_S8	1.26	1.34	1.41	1.52	3.52	3.65	3.90	3.90	4.09	4.31	4.73	4.73	ns
LVC MOS33_S12	1.26	1.34	1.41	1.52	3.09	3.21	3.46	3.46	3.65	3.87	4.29	4.29	ns
LVC MOS33_S16	1.26	1.34	1.41	1.52	3.40	3.52	3.77	3.78	3.97	4.18	4.60	4.60	ns
LVC MOS33_F4	1.26	1.34	1.41	1.52	3.26	3.38	3.64	3.64	3.83	4.04	4.46	4.46	ns
LVC MOS33_F8	1.26	1.34	1.41	1.52	2.74	2.87	3.12	3.12	3.31	3.52	3.95	3.95	ns
LVC MOS33_F12	1.26	1.34	1.41	1.52	2.56	2.68	2.93	2.93	3.12	3.34	3.76	3.76	ns
LVC MOS33_F16	1.26	1.34	1.41	1.52	2.56	2.68	2.93	3.06	3.12	3.34	3.76	3.89	ns
LVC MOS25_S4	1.12	1.20	1.27	1.38	3.13	3.26	3.51	3.51	3.70	3.91	4.34	4.34	ns
LVC MOS25_S8	1.12	1.20	1.27	1.38	2.88	3.01	3.26	3.26	3.45	3.67	4.09	4.09	ns
LVC MOS25_S12	1.12	1.20	1.27	1.38	2.48	2.60	2.85	2.85	3.05	3.26	3.68	3.68	ns
LVC MOS25_S16	1.12	1.20	1.27	1.38	2.82	2.94	3.20	3.20	3.39	3.60	4.03	4.03	ns
LVC MOS25_F4	1.12	1.20	1.27	1.38	2.74	2.87	3.12	3.12	3.31	3.52	3.95	3.95	ns
LVC MOS25_F8	1.12	1.20	1.27	1.38	2.18	2.30	2.56	2.56	2.75	2.96	3.39	3.39	ns
LVC MOS25_F12	1.12	1.20	1.27	1.38	2.16	2.29	2.54	2.54	2.73	2.95	3.37	3.37	ns
LVC MOS25_F16	1.12	1.20	1.27	1.38	2.01	2.13	2.39	2.63	2.58	2.79	3.21	3.46	ns
LVC MOS18_S4	0.74	0.83	0.89	0.97	1.62	1.74	1.99	1.99	2.19	2.40	2.82	2.82	ns
LVC MOS18_S8	0.74	0.83	0.89	0.97	2.18	2.30	2.56	2.56	2.75	2.96	3.39	3.39	ns
LVC MOS18_S12	0.74	0.83	0.89	0.97	2.18	2.30	2.56	2.56	2.75	2.96	3.39	3.39	ns
LVC MOS18_S16	0.74	0.83	0.89	0.97	1.52	1.65	1.90	1.90	2.09	2.31	2.73	2.73	ns
LVC MOS18_S24	0.74	0.83	0.89	0.97	1.60	1.72	1.98	2.40	2.17	2.38	2.81	3.23	ns
LVC MOS18_F4	0.74	0.83	0.89	0.97	1.45	1.57	1.82	1.82	2.01	2.23	2.65	2.65	ns
LVC MOS18_F8	0.74	0.83	0.89	0.97	1.68	1.80	2.06	2.06	2.25	2.46	2.89	2.89	ns
LVC MOS18_F12	0.74	0.83	0.89	0.97	1.68	1.80	2.06	2.06	2.25	2.46	2.89	2.89	ns
LVC MOS18_F16	0.74	0.83	0.89	0.97	1.40	1.52	1.77	1.78	1.97	2.18	2.60	2.60	ns
LVC MOS18_F24	0.74	0.83	0.89	0.97	1.34	1.46	1.71	2.28	1.90	2.12	2.54	3.10	ns
LVC MOS15_S4	0.77	0.86	0.93	0.96	2.05	2.18	2.43	2.43	2.62	2.84	3.26	3.26	ns
LVC MOS15_S8	0.77	0.86	0.93	0.96	2.09	2.21	2.46	2.46	2.65	2.87	3.29	3.29	ns
LVC MOS15_S12	0.77	0.86	0.93	0.96	1.59	1.71	1.96	1.96	2.15	2.37	2.79	2.79	ns
LVC MOS15_S16	0.77	0.86	0.93	0.96	1.59	1.71	1.96	1.96	2.15	2.37	2.79	2.79	ns

Table 50: 3.3V IOB High Range (HR) Switching Characteristics (Cont'd)

I/O Standard	T _{IOPI}				T _{IOOP}				T _{IOTP}				Units
	Speed Grade				Speed Grade				Speed Grade				
	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	-3	-2	-1C/-1I	-1Q	
LVC MOS15_F4	0.77	0.86	0.93	0.96	1.85	1.97	2.23	2.23	2.42	2.63	3.06	3.06	ns
LVC MOS15_F8	0.77	0.86	0.93	0.96	1.60	1.72	1.98	1.98	2.17	2.38	2.81	2.81	ns
LVC MOS15_F12	0.77	0.86	0.93	0.96	1.35	1.47	1.73	1.73	1.92	2.13	2.56	2.56	ns
LVC MOS15_F16	0.77	0.86	0.93	0.96	1.34	1.46	1.71	2.07	1.90	2.12	2.54	2.90	ns
LVC MOS12_S4	0.87	0.95	1.02	1.19	2.57	2.69	2.95	2.95	3.14	3.35	3.78	3.78	ns
LVC MOS12_S8	0.87	0.95	1.02	1.19	2.09	2.21	2.46	2.46	2.65	2.87	3.29	3.29	ns
LVC MOS12_S12	0.87	0.95	1.02	1.19	1.79	1.91	2.17	2.17	2.36	2.57	2.99	3.00	ns
LVC MOS12_F4	0.87	0.95	1.02	1.19	1.98	2.10	2.35	2.35	2.54	2.76	3.18	3.18	ns
LVC MOS12_F8	0.87	0.95	1.02	1.19	1.54	1.66	1.92	1.92	2.11	2.32	2.75	2.75	ns
LVC MOS12_F12	0.87	0.95	1.02	1.19	1.38	1.51	1.76	1.76	1.95	2.16	2.59	2.59	ns
SSTL135_S	0.67	0.75	0.82	0.88	1.35	1.47	1.73	1.73	1.92	2.13	2.56	2.56	ns
SSTL15_S	0.60	0.68	0.75	0.75	1.30	1.43	1.68	1.71	1.87	2.09	2.51	2.54	ns
SSTL18_I_S	0.67	0.75	0.82	0.86	1.67	1.79	2.04	2.04	2.23	2.45	2.87	2.87	ns
SSTL18_II_S	0.67	0.75	0.82	0.88	1.31	1.43	1.68	1.68	1.87	2.09	2.51	2.51	ns
DIFF_SSTL135_S	0.68	0.76	0.83	0.88	1.35	1.47	1.73	1.73	1.92	2.13	2.56	2.56	ns
DIFF_SSTL15_S	0.68	0.76	0.83	0.88	1.30	1.43	1.68	1.71	1.87	2.09	2.51	2.54	ns
DIFF_SSTL18_I_S	0.71	0.79	0.86	0.88	1.68	1.80	2.06	2.06	2.25	2.46	2.89	2.89	ns
DIFF_SSTL18_II_S	0.71	0.79	0.86	0.88	1.38	1.51	1.76	1.76	1.95	2.17	2.59	2.59	ns
SSTL135_F	0.67	0.75	0.82	0.88	1.12	1.24	1.49	1.49	1.69	1.90	2.32	2.32	ns
SSTL15_F	0.60	0.68	0.75	0.75	1.07	1.19	1.45	1.45	1.64	1.85	2.28	2.28	ns
SSTL18_I_F	0.67	0.75	0.82	0.86	1.12	1.24	1.49	1.53	1.69	1.90	2.32	2.35	ns
SSTL18_II_F	0.67	0.75	0.82	0.88	1.12	1.24	1.49	1.51	1.69	1.90	2.32	2.34	ns
DIFF_SSTL135_F	0.68	0.76	0.83	0.88	1.12	1.24	1.49	1.49	1.69	1.90	2.32	2.32	ns
DIFF_SSTL15_F	0.68	0.76	0.83	0.88	1.07	1.19	1.45	1.45	1.64	1.85	2.28	2.28	ns
DIFF_SSTL18_I_F	0.71	0.79	0.86	0.88	1.23	1.35	1.60	1.60	1.79	2.01	2.43	2.43	ns
DIFF_SSTL18_II_F	0.71	0.79	0.86	0.88	1.21	1.33	1.59	1.59	1.78	1.99	2.42	2.42	ns

Table 51 specifies the values of T_{IOTPHZ} and T_{IOBUFDISABLE}. T_{IOTPHZ} is described as the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is enabled (i.e., a high impedance state). T_{IOBUFDISABLE} is described as the IOB delay from IBUFDISABLE to O output. In HR I/O banks, the internal IN_TERM termination turn-off time is always faster than T_{IOTPHZ} when the INTERMDISABLE pin is used.

Table 51: IOB 3-state Output Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T _{IOTPHZ}	T input to pad high-impedance	2.06	2.19	2.37	2.37	ns
T _{IOBUFDISABLE}	IBUF turn-on time from IBUFDISABLE to O output	2.11	2.30	2.60	2.60	ns

Input/Output Logic Switching Characteristics

Table 52: ILOGIC Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Setup/Hold						
T _{ICE1CK} /T _{ICKCE1}	CE1 pin setup/hold with respect to CLK	0.48/0.02	0.54/0.02	0.76/0.02	0.76/0.02	ns
T _{ISRCK} /T _{ICKSR}	SR pin setup/hold with respect to CLK	0.60/0.01	0.70/0.01	1.13/0.01	1.13/0.01	ns
T _{IDOCK} /T _{IOCKD}	D pin setup/hold with respect to CLK without Delay	0.01/0.27	0.01/0.29	0.01/0.33	0.01/0.33	ns
T _{IDOCKD} /T _{IOCKDD}	DDLY pin setup/hold with respect to CLK (using IDELAY)	0.02/0.27	0.02/0.29	0.02/0.33	0.02/0.33	ns
Combinatorial						
T _{IDI}	D pin to O pin propagation delay, no Delay	0.11	0.11	0.13	0.13	ns
T _{IDID}	DDLY pin to O pin propagation delay (using IDELAY)	0.11	0.12	0.14	0.14	ns
Sequential Delays						
T _{IDLO}	D pin to Q1 pin using flip-flop as a latch without Delay	0.41	0.44	0.51	0.51	ns
T _{IDLOD}	DDLY pin to Q1 pin using flip-flop as a latch (using IDELAY)	0.41	0.44	0.51	0.51	ns
T _{ICKQ}	CLK to Q outputs	0.53	0.57	0.66	0.66	ns
T _{RQ_ILOGIC}	SR pin to OQ/TQ out	0.96	1.08	1.32	1.32	ns
T _{GSRQ_ILOGIC}	Global set/reset to Q outputs	7.60	7.60	10.51	10.51	ns
Set/Reset						
T _{RPW_ILOGIC}	Minimum pulse width, SR inputs	0.61	0.72	0.72	0.72	ns, Min

Table 53: OLOGIC Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Setup/Hold						
T _{ODCK} /T _{OCKD}	D1/D2 pins setup/hold with respect to CLK	0.67/−0.11	0.71/−0.11	0.84/−0.11	0.84/−0.06	ns
T _{OOCECK} /T _{OCKOCE}	OCE pin setup/hold with respect to CLK	0.32/0.58	0.34/0.58	0.51/0.58	0.51/0.58	ns
T _{OSRCK} /T _{OCKSR}	SR pin setup/hold with respect to CLK	0.37/0.21	0.44/0.21	0.80/0.21	0.80/0.21	ns
T _{OTCK} /T _{OCKT}	T1/T2 pins setup/hold with respect to CLK	0.69/−0.14	0.73/−0.14	0.89/−0.14	0.89/−0.11	ns
T _{OTCECK} /T _{OCKTCE}	TCE pin setup/hold with respect to CLK	0.32/0.01	0.34/0.01	0.51/0.01	0.51/0.01	ns
Combinatorial						
T _{ODQ}	D1 to OQ out or T1 to TQ out	0.83	0.96	1.16	1.16	ns
Sequential Delays						
T _{OCKQ}	CLK to OQ/TQ out	0.47	0.49	0.56	0.56	ns
T _{RQ_OLOGIC}	SR pin to OQ/TQ out	0.72	0.80	0.95	0.95	ns
T _{GSRQ_OLOGIC}	Global set/reset to Q outputs	7.60	7.60	10.51	10.51	ns
Set/Reset						
T _{RPW_OLOGIC}	Minimum pulse width, SR inputs	0.64	0.74	0.74	0.74	ns, Min

Input Serializer/Deserializer Switching Characteristics

Table 54: ISERDES Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Setup/Hold for Control Lines						
T _{ISCKCK_BITSLLIP} / T _{ISCKC_BITSLLIP}	BITSLLIP pin setup/hold with respect to CLKDIV	0.01/0.14	0.02/0.15	0.02/0.17	0.02/0.17	ns
T _{ISCKCK_CE} / T _{ISCKC_CE} ⁽²⁾	CE pin setup/hold with respect to CLK (for CE1)	0.45/−0.01	0.50/−0.01	0.72/−0.01	0.72/−0.01	ns
T _{ISCKCK_CE2} / T _{ISCKC_CE2} ⁽²⁾	CE pin setup/hold with respect to CLKDIV (for CE2)	−0.10/0.33	−0.10/0.36	−0.10/0.40	−0.10/0.40	ns
Setup/Hold for Data Lines						
T _{ISDCK_D} /T _{ISCKD_D}	D pin setup/hold with respect to CLK	−0.02/0.12	−0.02/0.14	−0.02/0.17	−0.02/0.17	ns
T _{ISDCK_DDLY} / T _{ISCKD_DDLY}	DDLY pin setup/hold with respect to CLK (using IDELAY) ⁽¹⁾	−0.02/0.12	−0.02/0.14	−0.02/0.17	−0.02/0.17	ns
T _{ISDCK_D_DDR} / T _{ISCKD_D_DDR}	D pin setup/hold with respect to CLK at DDR mode	−0.02/0.12	−0.02/0.14	−0.02/0.17	−0.02/0.17	ns
T _{ISDCK_DDLY_DDR} / T _{ISCKD_DDLY_DDR}	D pin setup/hold with respect to CLK at DDR mode (using IDELAY) ⁽¹⁾	0.12/0.12	0.14/0.14	0.17/0.17	0.17/0.17	ns
Sequential Delays						
T _{ISCKO_Q}	CLKDIV to out at Q pin	0.53	0.54	0.66	0.66	ns
Propagation Delays						
T _{ISDO_DO}	D input to DO output pin	0.11	0.11	0.13	0.13	ns

Notes:

- Recorded at 0 tap value.
- T_{ISCK_CE2} and T_{ISCK_CE2} are reported as T_{ISCK_CE}/T_{ISCK_CE} in the timing report.

Output Serializer/Deserializer Switching Characteristics

Table 55: OSERDES Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Setup/Hold						
T _{OSDCK_D} /T _{OSCKD_D}	D input setup/hold with respect to CLKDIV	0.42/0.03	0.45/0.03	0.63/0.03	0.63/0.08	ns
T _{OSDCK_T} /T _{OSCKD_T} ⁽¹⁾	T input setup/hold with respect to CLK	0.69/−0.13	0.73/−0.13	0.88/−0.13	0.88/−0.13	ns
T _{OSDCK_T2} /T _{OSCKD_T2} ⁽¹⁾	T input setup/hold with respect to CLKDIV	0.31/−0.13	0.34/−0.13	0.39/−0.13	0.39/−0.13	ns
T _{OSCCK_OCE} /T _{OSCKC_OCE}	OCE input setup/hold with respect to CLK	0.32/0.58	0.34/0.58	0.51/0.58	0.51/0.58	ns
T _{OSCCK_S}	SR (reset) input setup with respect to CLKDIV	0.47	0.52	0.85	0.85	ns
T _{OSCCK_TCE} /T _{OSCKC_TCE}	TCE input setup/hold with respect to CLK	0.32/0.01	0.34/0.01	0.51/0.01	0.51/0.10	ns
Sequential Delays						
T _{OSCKO_OQ}	Clock to out from CLK to OQ	0.40	0.42	0.48	0.48	ns
T _{OSCKO_TQ}	Clock to out from CLK to TQ	0.47	0.49	0.56	0.56	ns
Combinatorial						
T _{OSDO_TTQ}	T input to TQ out	0.83	0.92	1.11	1.11	ns

Notes:

- T_{OSCK_T2} and T_{OSCK_T2} are reported as T_{OSCK_T}/T_{OSCK_T} in the timing report.

Input Delay Switching Characteristics

Table 56: Input Delay Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
IDELAYCTRL						
T _{DLYCCO_RDY}	Reset to ready for IDELAYCTRL	3.67	3.67	3.67	3.67	μs
F _{IDELAYCTRL_REF}	Attribute REFCLK frequency = 200.0 ⁽¹⁾	200	200	200	200	MHz
	Attribute REFCLK frequency = 300.0 ⁽¹⁾	300	300	N/A	N/A	MHz
IDELAYCTRL_REF_PRECISION	REFCLK precision	±10	±10	±10	±10	MHz
T _{IDELAYCTRL_RPW}	Minimum reset pulse width	59.28	59.28	59.28	59.28	ns
IDELAY						
T _{IDELAYRESOLUTION}	IDELAY chain delay resolution	1/(32 x 2 x F _{REF})				ps
T _{IDELAYPAT_JIT}	Pattern dependent period jitter in delay chain for clock pattern. ⁽²⁾	0	0	0	0	ps per tap
	Pattern dependent period jitter in delay chain for random data pattern (PRBS 23) ⁽³⁾	±5	±5	±5	±5	ps per tap
	Pattern dependent period jitter in delay chain for random data pattern (PRBS 23) ⁽⁴⁾	±9	±9	±9	±9	ps per tap
T _{IDELAY_CLK_MAX}	Maximum frequency of CLK input to IDELAY	680.00	680.00	600.00	600.00	MHz
T _{IDCCK_CE} / T _{IDCKC_CE}	CE pin setup/hold with respect to C for IDELAY	0.12/0.11	0.16/0.13	0.21/0.16	0.21/0.16	ns
T _{IDCCK_INC} / T _{IDCKC_INC}	INC pin setup/hold with respect to C for IDELAY	0.12/0.16	0.14/0.18	0.16/0.22	0.16/0.23	ns
T _{IDCCK_RST} / T _{IDCKC_RST}	RST pin setup/hold with respect to C for IDELAY	0.15/0.09	0.16/0.11	0.18/0.14	0.18/0.14	ns
T _{IDDO} / T _{IDATAIN}	Propagation delay through IDELAY	Note 5	Note 5	Note 5	Note 5	ps

Notes:

1. Average tap delay at 200 MHz = 78 ps, at 300 MHz = 52 ps.
2. When HIGH_PERFORMANCE mode is set to TRUE or FALSE.
3. When HIGH_PERFORMANCE mode is set to TRUE.
4. When HIGH_PERFORMANCE mode is set to FALSE.
5. Delay depends on IDELAY tap setting. See the timing report for actual values.

Table 57: IO_FIFO Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
IO_FIFO Clock to Out Delays						
T _{OFFCKO_DO}	RDCLK to Q outputs	0.55	0.60	0.68	0.68	ns
T _{CKO_FLAGS}	Clock to IO_FIFO flags	0.55	0.61	0.77	0.77	ns
Setup/Hold						
T _{CCK_D} /T _{CKC_D}	D inputs to WRCLK	0.47/0.02	0.51/0.02	0.58/0.02	0.58/0.18	ns
T _{IFFCKC_WREN} /T _{IFFCKC_WREN}	WREN to WRCLK	0.42/−0.01	0.47/−0.01	0.53/−0.01	0.53/−0.01	ns
T _{OFFCKC_RDEN} /T _{OFFCKC_RDEN}	RDEN to RDCLK	0.53/0.02	0.58/0.02	0.66/0.02	0.66/0.02	ns
Minimum Pulse Width						
T _{PWH_IO_FIFO}	RESET, RDCLK, WRCLK	1.62	2.15	2.15	2.15	ns
T _{PWL_IO_FIFO}	RESET, RDCLK, WRCLK	1.62	2.15	2.15	2.15	ns
Maximum Frequency						
F _{MAX}	RDCLK and WRCLK	266.67	200.00	200.00	200.00	MHz

CLB Switching Characteristics

Table 58: CLB Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Combinatorial Delays						
T _{ILO}	An – Dn LUT address to A	0.10	0.11	0.13	0.13	ns, Max
T _{ILO_2}	An – Dn LUT address to AMUX/CMUX	0.27	0.30	0.36	0.36	ns, Max
T _{ILO_3}	An – Dn LUT address to BMUX_A	0.42	0.46	0.55	0.55	ns, Max
T _{ITO}	An – Dn inputs to A – D Q outputs	0.94	1.05	1.27	1.27	ns, Max
T _{AXA}	AX inputs to AMUX output	0.62	0.69	0.84	0.84	ns, Max
T _{AXB}	AX inputs to BMUX output	0.58	0.66	0.83	0.83	ns, Max
T _{AXC}	AX inputs to CMUX output	0.60	0.68	0.82	0.82	ns, Max
T _{AXD}	AX inputs to DMUX output	0.68	0.75	0.90	0.90	ns, Max
T _{BXB}	BX inputs to BMUX output	0.51	0.57	0.69	0.69	ns, Max
T _{BXD}	BX inputs to DMUX output	0.62	0.69	0.82	0.82	ns, Max
T _{CXC}	CX inputs to CMUX output	0.42	0.48	0.58	0.58	ns, Max
T _{CXD}	CX inputs to DMUX output	0.53	0.59	0.71	0.71	ns, Max
T _{DXD}	DX inputs to DMUX output	0.52	0.58	0.70	0.70	ns, Max
Sequential Delays						
T _{CKO}	Clock to AQ – DQ outputs	0.40	0.44	0.53	0.53	ns, Max
T _{SHCKO}	Clock to AMUX – DMUX outputs	0.47	0.53	0.66	0.66	ns, Max
Setup and Hold Times of CLB Flip-Flops Before/After Clock CLK						
T _{AS} /T _{AH}	A _N – D _N input to CLK on A – D flip-flops	0.07/0.12	0.09/0.14	0.11/0.18	0.11/0.28	ns, Min
T _{DICK} /T _{CKDI}	A _X – D _X input to CLK on A – D flip-flops	0.06/0.19	0.07/0.21	0.09/0.26	0.09/0.35	ns, Min
	A _X – D _X input through MUXs and/or carry logic to CLK on A – D flip-flops	0.59/0.08	0.66/0.09	0.81/0.11	0.81/0.20	ns, Min
T _{CECK_CLB} /T _{CKCE_CLB}	CE input to CLK on A – D flip-flops	0.15/0.00	0.17/0.00	0.21/0.01	0.21/0.13	ns, Min
T _{SRCK} /T _{CKSR}	SR input to CLK on A – D flip-flops	0.38/0.03	0.43/0.04	0.53/0.05	0.53/0.18	ns, Min
Set/Reset						
T _{SRMIN}	SR input minimum pulse width	0.52	0.78	1.04	1.04	ns, Min
T _{RQ}	Delay from SR input to AQ – DQ flip-flops	0.53	0.59	0.71	0.71	ns, Max
T _{CEO}	Delay from CE input to AQ – DQ flip-flops	0.52	0.58	0.70	0.70	ns, Max
F _{TOG}	Toggle frequency (for export control)	1412	1286	1098	1098	MHz

Notes:

- These items are of interest for carry-chain applications.

CLB Distributed RAM Switching Characteristics (SLICEM Only)

Table 59: CLB Distributed RAM Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Sequential Delays						
T _{SHCKO} ⁽¹⁾	Clock to A – B outputs	0.98	1.09	1.32	1.32	ns, Max
T _{SHCKO_1}	Clock to AMUX – BMUX outputs	1.37	1.53	1.86	1.86	ns, Max
Setup and Hold Times Before/After Clock CLK						
T _{DS_LRAM} /T _{DH_LRAM}	A – D inputs to CLK	0.54/0.28	0.60/0.30	0.72/0.35	0.72/0.37	ns, Min
T _{AS_LRAM} /T _{AH_LRAM}	Address An inputs to clock	0.27/0.55	0.30/0.60	0.37/0.70	0.37/0.71	ns, Min
	Address An inputs through MUXs and/or carry logic to clock	0.69/0.18	0.77/0.21	0.94/0.26	0.94/0.35	ns, Min
T _{WS_LRAM} /T _{WH_LRAM}	WE input to clock	0.38/0.10	0.43/0.12	0.53/0.17	0.53/0.17	ns, Min
T _{CECK_LRAM} /T _{CKCE_LRAM}	CE input to CLK	0.39/0.10	0.44/0.11	0.53/0.17	0.53/0.17	ns, Min
Clock CLK						
T _{MPW_LRAM}	Minimum pulse width	1.05	1.13	1.25	1.25	ns, Min
T _{MCP}	Minimum clock period	2.10	2.26	2.50	2.50	ns, Min

Notes:

1. T_{SHCKO} also represents the CLK to XMUX output. Refer to the timing report for the CLK to XMUX path.

CLB Shift Register Switching Characteristics (SLICEM Only)

Table 60: CLB Shift Register Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Sequential Delays						
T _{REG}	Clock to A – D outputs	1.19	1.33	1.61	1.61	ns, Max
T _{REG_MUX}	Clock to AMUX – DMUX output	1.58	1.77	2.15	2.15	ns, Max
T _{REG_M31}	Clock to DMUX output via M31 output	1.12	1.23	1.46	1.46	ns, Max
Setup and Hold Times Before/After Clock CLK						
T _{WS_SHFREG} /T _{WH_SHFREG}	WE input	0.37/0.10	0.41/0.12	0.51/0.17	0.51/0.17	ns, Min
T _{CECK_SHFREG} /T _{CKCE_SHFREG}	CE input to CLK	0.37/0.10	0.42/0.11	0.52/0.17	0.52/0.17	ns, Min
T _{DS_SHFREG} /T _{DH_SHFREG}	A – D inputs to CLK	0.33/0.34	0.37/0.37	0.44/0.43	0.44/0.44	ns, Min
Clock CLK						
T _{MPW_SHFREG}	Minimum pulse width	0.77	0.86	0.98	0.98	ns, Min

Block RAM and FIFO Switching Characteristics

Table 61: Block RAM and FIFO Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Block RAM and FIFO Clock to Out Delays						
T_{RCKO_DO} and $T_{RCKO_DO_REG}^{(1)}$	Clock CLK to DOUT output (without output register) ⁽²⁾⁽³⁾	1.85	2.13	2.46	2.46	ns, Max
	Clock CLK to DOUT output (with output register) ⁽⁴⁾⁽⁵⁾	0.64	0.74	0.89	0.89	ns, Max
$T_{RCKO_DO_ECC}$ and $T_{RCKO_DO_ECC_REG}$	Clock CLK to DOUT output with ECC (without output register) ⁽²⁾⁽³⁾	2.77	3.04	3.84	3.84	ns, Max
	Clock CLK to DOUT output with ECC (with output register) ⁽⁴⁾⁽⁵⁾	0.73	0.81	0.94	0.94	ns, Max
$T_{RCKO_DO_CASCOU}$ and $T_{RCKO_DO_CASCOU_REG}$	Clock CLK to DOUT output with cascade (without output register) ⁽²⁾	2.61	2.88	3.30	3.30	ns, Max
	Clock CLK to DOUT output with cascade (with output register) ⁽⁴⁾	1.16	1.28	1.46	1.46	ns, Max
T_{RCKO_FLAGS}	Clock CLK to FIFO flags outputs ⁽⁶⁾	0.76	0.87	1.05	1.05	ns, Max
$T_{RCKO_POINTERS}$	Clock CLK to FIFO pointers outputs ⁽⁷⁾	0.94	1.02	1.15	1.15	ns, Max
$T_{RCKO_PARITY_ECC}$	Clock CLK to ECCPARITY in ECC encode only mode	0.78	0.85	0.94	0.94	ns, Max
$T_{RCKO_SDBIT_ECC}$ and $T_{RCKO_SDBIT_ECC_REG}$	Clock CLK to BITERR (without output register)	2.56	2.81	3.55	3.55	ns, Max
	Clock CLK to BITERR (with output register)	0.68	0.76	0.89	0.89	ns, Max
$T_{RCKO_RDADDR_ECC}$ and $T_{RCKO_RDADDR_ECC_REG}$	Clock CLK to RDADDR output with ECC (without output register)	0.75	0.88	1.07	1.07	ns, Max
	Clock CLK to RDADDR output with ECC (with output register)	0.84	0.93	1.08	1.08	ns, Max
Setup and Hold Times Before/After Clock CLK						
$T_{RCKK_ADDRA}/T_{RCKK_ADDRA}$	ADDR inputs ⁽⁸⁾	0.45/0.31	0.49/0.33	0.57/0.36	0.57/0.52	ns, Min
$T_{RDCK_DI_WF_NC}/T_{RCKD_DI_WF_NC}$	Data input setup/hold time when block RAM is configured in WRITE_FIRST or NO_CHANGE mode ⁽⁹⁾	0.58/0.60	0.65/0.63	0.74/0.67	0.74/0.67	ns, Min
$T_{RDCK_DI_RF}/T_{RCKD_DI_RF}$	Data input setup/hold time when block RAM is configured in READ_FIRST mode ⁽⁹⁾	0.20/0.29	0.22/0.34	0.25/0.41	0.25/0.50	ns, Min
$T_{RDCK_DI_ECC}/T_{RCKD_DI_ECC}$	DIN inputs with block RAM ECC in standard mode ⁽⁹⁾	0.50/0.43	0.55/0.46	0.63/0.50	0.63/0.50	ns, Min
	DIN inputs with block RAM ECC encode only ⁽⁹⁾	0.93/0.43	1.02/0.46	1.17/0.50	1.17/0.50	ns, Min
	DIN inputs with FIFO ECC in standard mode ⁽⁹⁾	1.04/0.56	1.15/0.59	1.32/0.64	1.32/0.64	ns, Min
$T_{RCKK_INJECTBITERR}/T_{RCKK_INJECTBITERR}$	Inject single/double bit error in ECC mode	0.58/0.35	0.64/0.37	0.74/0.40	0.74/0.52	ns, Min
$T_{RCKK_RDEN}/T_{RCKK_RDEN}$	Block RAM enable (EN) input	0.35/0.20	0.39/0.21	0.45/0.23	0.45/0.41	ns, Min
$T_{RCKK_REGCE}/T_{RCKK_REGCE}$	CE input of output register	0.24/0.15	0.29/0.15	0.36/0.16	0.36/0.39	ns, Min
$T_{RCKK_RSTREG}/T_{RCKK_RSTREG}$	Synchronous RSTREG input	0.29/0.07	0.32/0.07	0.35/0.07	0.35/0.17	ns, Min
$T_{RCKK_RSTRAM}/T_{RCKK_RSTRAM}$	Synchronous RSTRAM input	0.32/0.42	0.34/0.43	0.36/0.46	0.36/0.57	ns, Min
$T_{RCKK_WEA}/T_{RCKK_WEA}$	Write enable (WE) input (block RAM only)	0.44/0.18	0.48/0.19	0.54/0.20	0.54/0.42	ns, Min
$T_{RCKK_WREN}/T_{RCKK_WREN}$	WREN FIFO inputs	0.46/0.30	0.46/0.35	0.47/0.43	0.47/0.43	ns, Min
$T_{RCKK_RDEN}/T_{RCKK_RDEN}$	RDEN FIFO inputs	0.42/0.30	0.43/0.35	0.43/0.43	0.43/0.62	ns, Min

Table 61: Block RAM and FIFO Switching Characteristics (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Reset Delays						
T _{RCO_FLAGS}	Reset RST to FIFO flags/pointers ⁽¹⁰⁾	0.90	0.98	1.10	1.10	ns, Max
T _{RREC_RST} /T _{RREM_RST}	FIFO reset recovery and removal timing ⁽¹¹⁾	1.87/−0.81	2.07/−0.81	2.37/−0.81	2.37/−0.58	ns, Max
Maximum Frequency						
F _{MAX_BRAM_WF_NC}	Block RAM (write first and no change modes) When not in SDP RF mode.	509.68	460.83	388.20	388.20	MHz
F _{MAX_BRAM_RF_PERFORMANCE}	Block RAM (read first, performance mode) When in SDP RF mode but no address overlap between port A and port B.	509.68	460.83	388.20	388.20	MHz
F _{MAX_BRAM_RF_DELAYED_WRITE}	Block RAM (read first, delayed write mode) When in SDP RF mode and there is possibility of overlap between port A and port B addresses.	447.63	404.53	339.67	339.67	MHz
F _{MAX_CAS_WF_NC}	Block RAM cascade (write first, no change mode) When cascade but not in RF mode.	467.07	418.59	345.78	345.78	MHz
F _{MAX_CAS_RF_PERFORMANCE}	Block RAM cascade (read first, performance mode) When in cascade with RF mode and no possibility of address overlap/one port is disabled.	467.07	418.59	345.78	345.78	MHz
F _{MAX_CAS_RF_DELAYED_WRITE}	When in cascade RF mode and there is a possibility of address overlap between port A and port B.	405.35	362.19	297.35	297.35	MHz
F _{MAX_FIFO}	FIFO in all modes without ECC	509.68	460.83	388.20	388.20	MHz
F _{MAX_ECC}	Block RAM and FIFO in ECC configuration	410.34	365.10	297.53	297.53	MHz

Notes:

1. The timing report will report all of these parameters as T_{RCKO_DO}.
2. T_{RCKO_DOR} includes T_{RCKO_DOW}, T_{RCKO_DOPR}, and T_{RCKO_DOPW} as well as the B port equivalent timing parameters.
3. These parameters also apply to synchronous FIFO with DO_REG = 0.
4. T_{RCKO_DO} includes T_{RCKO_DOP} as well as the B port equivalent timing parameters.
5. These parameters also apply to multirate (asynchronous) and synchronous FIFO with DO_REG = 1.
6. T_{RCKO_FLAGS} includes the following parameters: T_{RCKO_AEMPTY}, T_{RCKO_AFULL}, T_{RCKO_EMPTY}, T_{RCKO_FULL}, T_{RCKO_RDERR}, and T_{RCKO_WRERR}.
7. T_{RCKO_POINTERS} includes both T_{RCKO_RDCOUNT} and T_{RCKO_WRCOUNT}.
8. The ADDR setup and hold must be met when EN is asserted (even when WE is deasserted). Otherwise, block RAM data corruption is possible.
9. These parameters include both A and B inputs as well as the parity inputs of A and B.
10. T_{RCO_FLAGS} includes the following flags: AEMPTY, AFULL, EMPTY, FULL, RDERR, WRERR, RDCOUNT, and WRCOUNT.
11. RDEN and WREN must be held Low prior to and during reset. The FIFO reset must be asserted for at least five positive clock edges of the slowest clock (WRCLK or RDCLK).

DSP48E1 Switching Characteristics

Table 62: DSP48E1 Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Setup and Hold Times of Data/Control Pins to the Input Register Clock						
T _{DSPDCK_A_AREG} / T _{DSPCKD_A_AREG}	A input to A register CLK	0.26/0.12	0.30/0.13	0.37/0.14	0.37/0.28	ns
T _{DSPDCK_B_BREG} /T _{DSPCKD_B_BREG}	B input to B register CLK	0.33/0.15	0.38/0.16	0.45/0.18	0.45/0.25	ns
T _{DSPDCK_C_CREG} /T _{DSPCKD_C_CREG}	C input to C register CLK	0.17/0.17	0.20/0.19	0.24/0.21	0.24/0.26	ns
T _{DSPDCK_D_DREG} /T _{DSPCKD_D_DREG}	D input to D register CLK	0.25/0.25	0.32/0.27	0.42/0.27	0.42/0.42	ns
T _{DSPDCK_ACIN_AREG} / T _{DSPCKD_ACIN_AREG}	ACIN input to A register CLK	0.23/0.12	0.27/0.13	0.32/0.14	0.32/0.17	ns
T _{DSPDCK_BCIN_BREG} / T _{DSPCKD_BCIN_BREG}	BCIN input to B register CLK	0.25/0.15	0.29/0.16	0.36/0.18	0.36/0.18	ns
Setup and Hold Times of Data Pins to the Pipeline Register Clock						
T _{DSPDCK_{A,B}_MREG_MULT} / T _{DSPCKD_B_MREG_MULT}	{A, B,} input to M register CLK using multiplier	2.40/–0.01	2.76/–0.01	3.29/–0.01	3.29/–0.01	ns
T _{DSPDCK_{A,B}_ADREG} / T _{DSPCKD_D_ADREG}	{A, D} input to AD register CLK	1.29/–0.02	1.48/–0.02	1.76/–0.02	1.76/–0.02	ns
Setup and Hold Times of Data/Control Pins to the Output Register Clock						
T _{DSPDCK_{A,B}_PREG_MULT} / T _{DSPCKD_{A,B}_PREG_MULT}	{A, B} input to P register CLK using multiplier	4.02/–0.28	4.60/–0.28	5.48/–0.28	5.48/–0.28	ns
T _{DSPDCK_D_PREG_MULT} / T _{DSPCKD_D_PREG_MULT}	D input to P register CLK using multiplier	3.93/–0.73	4.50/–0.73	5.35/–0.73	5.35/–0.73	ns
T _{DSPDCK_{A,B}_PREG} / T _{DSPCKD_{A,B}_PREG}	A or B input to P register CLK not using multiplier	1.73/–0.28	1.98/–0.28	2.35/–0.28	2.35/–0.28	ns
T _{DSPDCK_C_PREG} / T _{DSPCKD_C_PREG}	C input to P register CLK not using multiplier	1.54/–0.26	1.76/–0.26	2.10/–0.26	2.10/–0.26	ns
T _{DSPDCK_PCIN_PREG} / T _{DSPCKD_PCIN_PREG}	PCIN input to P register CLK	1.32/–0.15	1.51/–0.15	1.80/–0.15	1.80/–0.15	ns
Setup and Hold Times of the CE Pins						
T _{DSPDCK_{CEA;CEB}_{AREG;BREG}} / T _{DSPCKD_{CEA;CEB}_{AREG;BREG}}	{CEA; CEB} input to {A; B} register CLK	0.35/0.06	0.42/0.08	0.52/0.11	0.52/0.11	ns
T _{DSPDCK_CEC_CREG} / T _{DSPCKD_CEC_CREG}	CEC input to C register CLK	0.28/0.10	0.34/0.11	0.42/0.13	0.42/0.13	ns
T _{DSPDCK_CED_DREG} / T _{DSPCKD_CED_DREG}	CED input to D register CLK	0.36/–0.03	0.43/–0.03	0.52/–0.03	0.52/–0.03	ns
T _{DSPDCK_CEM_MREG} / T _{DSPCKD_CEM_MREG}	CEM input to M register CLK	0.17/0.18	0.21/0.20	0.27/0.23	0.27/0.23	ns
T _{DSPDCK_CEP_PREG} / T _{DSPCKD_CEP_PREG}	CEP input to P register CLK	0.36/0.01	0.43/0.01	0.53/0.01	0.53/0.01	ns
Setup and Hold Times of the RST Pins						
T _{DSPDCK_{RSTA;RSTB}_{AREG;BREG}} / T _{DSPCKD_{RSTA;RSTB}_{AREG;BREG}}	{RSTA, RSTB} input to {A, B} register CLK	0.41/0.11	0.46/0.13	0.55/0.15	0.55/0.24	ns
T _{DSPDCK_RSTC_CREG} / T _{DSPCKD_RSTC_CREG}	RSTC input to C register CLK	0.07/0.10	0.08/0.11	0.09/0.12	0.09/0.25	ns
T _{DSPDCK_RSTD_DREG} / T _{DSPCKD_RSTD_DREG}	RSTD input to D register CLK	0.44/0.07	0.50/0.08	0.59/0.09	0.59/0.09	ns
T _{DSPDCK_RSTM_MREG} / T _{DSPCKD_RSTM_MREG}	RSTM input to M register CLK	0.21/0.22	0.23/0.24	0.27/0.28	0.27/0.28	ns
T _{DSPDCK_RSTP_PREG} / T _{DSPCKD_RSTP_PREG}	RSTP input to P register CLK	0.27/0.01	0.30/0.01	0.35/0.01	0.35/0.03	ns

Table 62: DSP48E1 Switching Characteristics (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Combinatorial Delays from Input Pins to Output Pins						
T _{DSPDO_A_CARRYOUT_MULT}	A input to CARRYOUT output using multiplier	3.79	4.35	5.18	5.18	ns
T _{DSPDO_D_P_MULT}	D input to P output using multiplier	3.72	4.26	5.07	5.07	ns
T _{DSPDO_B_P}	B input to P output not using multiplier	1.53	1.75	2.08	2.08	ns
T _{DSPDO_C_P}	C input to P output	1.33	1.53	1.82	1.82	ns
Combinatorial Delays from Input Pins to Cascading Output Pins						
T _{DSPDO_{A; B}_{ACOUT; BCOUT}}	{A, B} input to {ACOUT, BCOUT} output	0.55	0.63	0.74	0.74	ns
T _{DSPDO_{A, B}_CARRYCASCOUT_MULT}	{A, B} input to CARRYCASCOUT output using multiplier	4.06	4.65	5.54	5.54	ns
T _{DSPDO_D_CARRYCASCOUT_MULT}	D input to CARRYCASCOUT output using multiplier	3.97	4.54	5.40	5.40	ns
T _{DSPDO_{A, B}_CARRYCASCOUT}	{A, B} input to CARRYCASCOUT output not using multiplier	1.77	2.03	2.41	2.41	ns
T _{DSPDO_C_CARRYCASCOUT}	C input to CARRYCASCOUT output	1.58	1.81	2.15	2.15	ns
Combinatorial Delays from Cascading Input Pins to All Output Pins						
T _{DSPDO_ACIN_P_MULT}	ACIN input to P output using multiplier	3.65	4.19	5.00	5.00	ns
T _{DSPDO_ACIN_P}	ACIN input to P output not using multiplier	1.37	1.57	1.88	1.88	ns
T _{DSPDO_ACIN_ACOUT}	ACIN input to ACOUT output	0.38	0.44	0.53	0.53	ns
T _{DSPDO_ACIN_CARRYCASCOUT_MULT}	ACIN input to CARRYCASCOUT output using multiplier	3.90	4.47	5.33	5.33	ns
T _{DSPDO_ACIN_CARRYCASCOUT}	ACIN input to CARRYCASCOUT output not using multiplier	1.61	1.85	2.21	2.21	ns
T _{DSPDO_PCIN_P}	PCIN input to P output	1.11	1.28	1.52	1.52	ns
T _{DSPDO_PCIN_CARRYCASCOUT}	PCIN input to CARRYCASCOUT output	1.36	1.56	1.85	1.85	ns
Clock to Outs from Output Register Clock to Output Pins						
T _{DSPCKO_P_PREG}	CLK PREG to P output	0.33	0.37	0.44	0.44	ns
T _{DSPCKO_CARRYCASCOUT_PREG}	CLK PREG to CARRYCASCOUT output	0.52	0.59	0.69	0.69	ns
Clock to Outs from Pipeline Register Clock to Output Pins						
T _{DSPCKO_P_MREG}	CLK MREG to P output	1.68	1.93	2.31	2.31	ns
T _{DSPCKO_CARRYCASCOUT_MREG}	CLK MREG to CARRYCASCOUT output	1.92	2.21	2.64	2.64	ns
T _{DSPCKO_P_ADREG_MULT}	CLK ADREG to P output using multiplier	2.72	3.10	3.69	3.69	ns
T _{DSPCKO_CARRYCASCOUT_ADREG_MULT}	CLK ADREG to CARRYCASCOUT output using multiplier	2.96	3.38	4.02	4.02	ns

Table 62: DSP48E1 Switching Characteristics (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Clock to Outs from Input Register Clock to Output Pins						
T _{DSPCKO_P_AREG_MULT}	CLK AREG to P output using multiplier	3.94	4.51	5.37	5.37	ns
T _{DSPCKO_P_BREG}	CLK BREG to P output not using multiplier	1.64	1.87	2.22	2.22	ns
T _{DSPCKO_P_CREG}	CLK CREG to P output not using multiplier	1.69	1.93	2.30	2.30	ns
T _{DSPCKO_P_DREG_MULT}	CLK DREG to P output using multiplier	3.91	4.48	5.32	5.32	ns
Clock to Outs from Input Register Clock to Cascading Output Pins						
T _{DSPCKO_{ACOUT; BCOUT}_{AREG; BREG}}	CLK (ACOUT, BCOUT) to {A,B} register output	0.64	0.73	0.87	0.87	ns
T _{DSPCKO_CARRYCASCOUT_{AREG; BREG}_MULT}	CLK (AREG, BREG) to CARRYCASCOUT output using multiplier	4.19	4.79	5.70	5.70	ns
T _{DSPCKO_CARRYCASCOUT_BREG}	CLK BREG to CARRYCASCOUT output not using multiplier	1.88	2.15	2.55	2.55	ns
T _{DSPCKO_CARRYCASCOUT_DREG_MULT}	CLK DREG to CARRYCASCOUT output using multiplier	4.16	4.76	5.65	5.65	ns
T _{DSPCKO_CARRYCASCOUT_CREG}	CLK CREG to CARRYCASCOUT output	1.94	2.21	2.63	2.63	ns
Maximum Frequency						
F _{MAX}	With all registers used	628.93	550.66	464.25	464.25	MHz
F _{MAX_PATDET}	With pattern detector	531.63	465.77	392.93	392.93	MHz
F _{MAX_MULT_NOMREG}	Two register multiply without MREG	349.28	305.62	257.47	257.47	MHz
F _{MAX_MULT_NOMREG_PATDET}	Two register multiply without MREG with pattern detect	317.26	277.62	233.92	233.92	MHz
F _{MAX_PREADD_MULT_NOADREG}	Without ADREG	397.30	346.26	290.44	290.44	MHz
F _{MAX_PREADD_MULT_NOADREG_PATDET}	Without ADREG with pattern detect	397.30	346.26	290.44	290.44	MHz
F _{MAX_NOPIPELINEREG}	Without pipeline registers (MREG, ADREG)	260.01	227.01	190.69	190.69	MHz
F _{MAX_NOPIPELINEREG_PATDET}	Without pipeline registers (MREG, ADREG) with pattern detect	241.72	211.15	177.43	177.43	MHz

Clock Buffers and Networks

Table 63: Global Clock Switching Characteristics (Including BUFGCTRL)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
$T_{BCCCK_CE}/T_{BCCCK_CE}^{(1)}$	CE pins setup/hold	0.13/0.39	0.14/0.41	0.18/0.42	0.18/0.84	ns
$T_{BCCCK_S}/T_{BCCCK_S}^{(1)}$	S pins setup/hold	0.13/0.39	0.14/0.41	0.18/0.42	0.18/0.84	ns
$T_{BCKO_O}^{(2)}$	BUFGCTRL delay from I/O to O	0.08	0.09	0.11	0.11	ns
Maximum Frequency						
F_{MAX_BUFG}	Global clock tree (BUFG)	628.00	628.00	464.00	464.00	MHz

Notes:

- T_{BCCCK_CE} and T_{BCCCK_CE} must be satisfied to assure glitch-free operation of the global clock when switching between clocks. These parameters do not apply to the BUFGMUX primitive that assures glitch-free operation. The other global clock setup and hold times are optional; only needing to be satisfied if device operation requires simulation matches on a cycle-for-cycle basis when switching between clocks.
- T_{BCKO_O} (BUFG delay from I/O to O) values are the same as T_{BCKO_O} values.

Table 64: Input/Output Clock Switching Characteristics (BUFIO)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T_{BIOCKO_O}	Clock to out delay from I to O	1.16	1.32	1.61	1.61	ns
Maximum Frequency						
F_{MAX_BUFIO}	I/O clock tree (BUFIO)	680.00	680.00	600.00	600.00	MHz

Table 65: Regional Clock Buffer Switching Characteristics (BUFR)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T_{BRCKO_O}	Clock to out delay from I to O	0.64	0.80	1.04	1.04	ns
$T_{BRCKO_O_BYP}$	Clock to out delay from I to O with Divide Bypass attribute set	0.35	0.41	0.54	0.54	ns
T_{BRDO_O}	Propagation delay from CLR to O	0.85	0.89	1.14	1.14	ns
Maximum Frequency						
$F_{MAX_BUFR}^{(1)}$	Regional clock tree (BUFR)	420.00	375.00	315.00	315.00	MHz

Notes:

- The maximum input frequency to the BUFR and BUFMR is the BUFIO F_{MAX} frequency.

Table 66: Horizontal Clock Buffer Switching Characteristics (BUFH)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T_{BHCKO_O}	BUFH delay from I to O	0.11	0.11	0.14	0.14	ns
T_{BHCK_CE}/T_{BHCK_CE}	CE pin setup and hold	0.20/0.13	0.23/0.16	0.29/0.21	0.29/0.43	ns
Maximum Frequency						
F_{MAX_BUFH}	Horizontal clock buffer (BUFH)	628.00	628.00	464.00	464.00	MHz

Table 67: Duty-Cycle Distortion and Clock-Tree Skew

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
T _{DCD_CLK}	Global clock tree duty-cycle distortion ⁽¹⁾	All	0.20	0.20	0.20	0.20	ns
T _{CKSKEW}	Global clock tree skew ⁽²⁾	XC7Z010	0.27	0.27	0.27	N/A	ns
		XC7Z015				N/A	ns
		XC7Z020	0.33	0.38	0.42	N/A	ns
		XA7Z010	N/A	N/A	0.27	0.27	ns
		XA7Z020	N/A	N/A	0.42	0.42	ns
		XQ7Z020	N/A	0.38	0.42	0.42	ns
T _{DCD_BUFIN}	I/O clock tree duty-cycle distortion	All	0.14	0.14	0.14	0.14	ns
T _{BUFIOSKEW}	I/O clock tree skew across one clock region	All	0.03	0.03	0.03	0.03	ns
T _{DCD_BUFR}	Regional clock tree duty-cycle distortion	All	0.18	0.18	0.18	0.18	ns

Notes:

- These parameters represent the worst-case duty-cycle distortion observable at the pins of the device using LVDS output buffers. For cases where other I/O standards are used, IBIS can be used to calculate any additional duty-cycle distortion that might be caused by asymmetrical rise/fall times.
- The T_{CKSKEW} value represents the worst-case clock-tree skew observable between sequential I/O elements. Significantly less clock-tree skew exists for I/O registers that are close to each other and fed by the same or adjacent clock-tree branches. Use the Xilinx Timing Analyzer tools to evaluate application specific clock skew.

MMCM Switching Characteristics

Table 68: MMCM Specification

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
MMCM_F _{INMAX}	Maximum input clock frequency	800.00	800.00	800.00	800.00	MHz
MMCM_F _{INMIN}	Minimum input clock frequency	10.00	10.00	10.00	10.00	MHz
MMCM_F _{INJITTER}	Maximum input clock period jitter	< 20% of clock input period or 1 ns Max				
MMCM_F _{INDUTY}	Allowable input duty cycle: 10—49 MHz	25	25	25	25	%
	Allowable input duty cycle: 50—199 MHz	30	30	30	30	%
	Allowable input duty cycle: 200—399 MHz	35	35	35	35	%
	Allowable input duty cycle: 400—499 MHz	40	40	40	40	%
	Allowable input duty cycle: >500 MHz	45	45	45	45	%
MMCM_F _{MIN_PSCLK}	Minimum dynamic phase-shift clock frequency	0.01	0.01	0.01	0.01	MHz
MMCM_F _{MAX_PSCLK}	Maximum dynamic phase-shift clock frequency	550.00	500.00	450.00	450.00	MHz
MMCM_F _{VCOMIN}	Minimum MMCM VCO frequency	600.00	600.00	600.00	600.00	MHz
MMCM_F _{VCOMAX}	Maximum MMCM VCO frequency	1600.00	1440.00	1200.00	1200.00	MHz
MMCM_F _{BANDWIDTH}	Low MMCM bandwidth at typical ⁽¹⁾	1.00	1.00	1.00	1.00	MHz
	High MMCM bandwidth at typical ⁽¹⁾	4.00	4.00	4.00	4.00	MHz
MMCM_T _{STATPHAOFFSET}	Static phase offset of the MMCM outputs ⁽²⁾	0.12	0.12	0.12	0.12	ns
MMCM_T _{OUTJITTER}	MMCM output jitter	Note 3				
MMCM_T _{OUTDUTY}	MMCM output clock duty-cycle precision ⁽⁴⁾	0.20	0.20	0.20	0.20	ns
MMCM_T _{LOCKMAX}	MMCM maximum lock time	100.00	100.00	100.00	100.00	μs
MMCM_F _{OUTMAX}	MMCM maximum output frequency	800.00	800.00	800.00	800.00	MHz
MMCM_F _{OUTMIN}	MMCM minimum output frequency ⁽⁵⁾⁽⁶⁾	4.69	4.69	4.69	4.69	MHz

Table 68: MMCM Specification (Cont'd)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
MMCM_T _{EXTFDVAR}	External clock feedback variation	< 20% of clock input period or 1 ns Max				
MMCM_RST _{MINPULSE}	Minimum reset pulse width	5.00	5.00	5.00	5.00	ns
MMCM_F _{PFDMAX}	Maximum frequency at the phase frequency detector	550.00	500.00	450.00	450.00	MHz
MMCM_F _{PFDMIN}	Minimum frequency at the phase frequency detector	10.00	10.00	10.00	10.00	MHz
MMCM_T _{FBDELAY}	Maximum delay in the feedback path	3 ns Max or one CLKIN cycle				
MMCM Switching Characteristics Setup and Hold						
T _{MMCMDCK_PSEN} / T _{MMCMCKD_PSEN}	Setup and hold of phase-shift enable	1.04/0.00	1.04/0.00	1.04/0.00	1.04/0.00	ns
T _{MMCMDCK_PSINCDEC} / T _{MMCMCKD_PSINCDEC}	Setup and hold of phase-shift increment/decrement	1.04/0.00	1.04/0.00	1.04/0.00	1.04/0.00	ns
T _{MMCMCKO_PSDONE}	Phase shift clock-to-out of PSDONE	0.59	0.68	0.81	0.81	ns
Dynamic Reconfiguration Port (DRP) for MMCM Before and After DCLK						
T _{MMCMDCK_DADDR} / T _{MMCMCKD_DADDR}	DADDR setup/hold	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{MMCMDCK_DI} / T _{MMCMCKD_DI}	DI setup/hold	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{MMCMDCK_DEN} / T _{MMCMCKD_DEN}	DEN setup/hold	1.76/0.00	1.97/0.00	2.29/0.00	2.29/0.00	ns, Min
T _{MMCMDCK_DWE} / T _{MMCMCKD_DWE}	DWE setup/hold	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{MMCMCKO_DRDY}	CLK to out of DRDY	0.65	0.72	0.99	0.99	ns, Max
F _{DCK}	DCLK frequency	200.00	200.00	200.00	200.00	MHz, Max

Notes:

1. The MMCM does not filter typical spread-spectrum input clocks because they are usually far below the bandwidth filter frequencies.
2. The static offset is measured between any MMCM outputs with identical phase.
3. Values for this parameter are available in the Clocking Wizard.
See http://www.xilinx.com/products/intellectual-property/clocking_wizard.htm.
4. Includes global clock buffer.
5. Calculated as F_{VCO}/128 assuming output duty cycle is 50%.
6. When CLKOUT4_CASCADE = TRUE, MMCM_F_{OUTMIN} is 0.036 MHz.

PLL Switching Characteristics

Table 69: PLL Specification

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
PLL_F _{INMAX}	Maximum input clock frequency	800.00	800.00	800.00	800.00	MHz
PLL_F _{INMIN}	Minimum input clock frequency	19.00	19.00	19.00	19.00	MHz
PLL_F _{INJITTER}	Maximum input clock period jitter	< 20% of clock input period or 1 ns Max				
PLL_F _{INDUTY}	Allowable input duty cycle: 19—49 MHz	25	25	25	25	%
	Allowable input duty cycle: 50—199 MHz	30	30	30	30	%
	Allowable input duty cycle: 200—399 MHz	35	35	35	35	%
	Allowable input duty cycle: 400—499 MHz	40	40	40	40	%
	Allowable input duty cycle: >500 MHz	45	45	45	45	%
PLL_F _{VCOMIN}	Minimum PLL VCO frequency	800.00	800.00	800.00	800.00	MHz
PLL_F _{VCOMAX}	Maximum PLL VCO frequency	2133.00	1866.00	1600.00	1600.00	MHz
PLL_F _{BANDWIDTH}	Low PLL bandwidth at typical ⁽¹⁾	1.00	1.00	1.00	1.00	MHz
	High PLL bandwidth at typical ⁽¹⁾	4.00	4.00	4.00	4.00	MHz
PLL_T _{STATPHAOFFSET}	Static phase offset of the PLL outputs ⁽²⁾	0.12	0.12	0.12	0.12	ns
PLL_T _{OUTJITTER}	PLL output jitter	Note 3				
PLL_T _{OUTDUTY}	PLL output clock duty-cycle precision ⁽⁴⁾	0.20	0.20	0.20	0.20	ns
PLL_T _{LOCKMAX}	PLL maximum lock time	100.00	100.00	100.00	100.00	μs
PLL_F _{OUTMAX}	PLL maximum output frequency	800.00	800.00	800.00	800.00	MHz
PLL_F _{OUTMIN}	PLL minimum output frequency ⁽⁵⁾	6.25	6.25	6.25	6.25	MHz
PLL_T _{EXTFDVAR}	External clock feedback variation	< 20% of clock input period or 1 ns Max				
PLL_RST _{MINPULSE}	Minimum reset pulse width	5.00	5.00	5.00	5.00	ns
PLL_F _{PFDMAX}	Maximum frequency at the phase frequency detector	550.00	500.00	450.00	450.00	MHz
PLL_F _{PFDMIN}	Minimum frequency at the phase frequency detector	19.00	19.00	19.00	19.00	MHz
PLL_T _{FBDELAY}	Maximum delay in the feedback path	3 ns Max or one CLKIN cycle				
Dynamic Reconfiguration Port (DRP) for PLL Before and After DCLK						
T _{PLLCKC_DADDR} /T _{PLLCKC_DADDR}	Setup and hold of D address	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{PLLCKC_DI} /T _{PLLCKC_DI}	Setup and hold of D input	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{PLLCKC_DEN} /T _{PLLCKC_D EN}	Setup and hold of D enable	1.76/0.00	1.97/0.00	2.29/0.00	2.29/0.00	ns, Min
T _{PLLCKC_DWE} /T _{PLLCKC_D WE}	Setup and hold of D write enable	1.25/0.15	1.40/0.15	1.63/0.15	1.63/0.15	ns, Min
T _{PLLCKO_DRDY}	CLK to out of DRDY	0.65	0.72	0.99	0.99	ns, Max
F _{DCK}	DCLK frequency	200.00	200.00	200.00	200.00	MHz, Max

Notes:

1. The PLL does not filter typical spread-spectrum input clocks because they are usually far below the bandwidth filter frequencies.
2. The static offset is measured between any PLL outputs with identical phase.
3. Values for this parameter are available in the Clocking Wizard.
See http://www.xilinx.com/products/intellectual-property/clocking_wizard.htm.
4. Includes global clock buffer.
5. Calculated as F_{VCO}/128 assuming output duty cycle is 50%.

Device Pin-to-Pin Output Parameter Guidelines

Table 70: Clock-Capable Clock Input to Output Delay Without MMCM/PLL (Near Clock Region)

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, <i>without</i> MMCM/PLL.							
T _{ICKOF}	Clock-capable clock input and OUTFF without MMCM/PLL (near clock region)	XC7Z010	5.08	5.68	6.65	N/A	ns
		XC7Z015	5.34	5.96	6.90	N/A	ns
		XC7Z020	5.42	6.05	7.08	N/A	ns
		XA7Z010	N/A	N/A	6.65	6.65	ns
		XA7Z020	N/A	N/A	7.08	7.08	ns
		XQ7Z020	N/A	6.05	7.08	7.08	ns

Notes:

- This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

Table 71: Clock-Capable Clock Input to Output Delay Without MMCM/PLL (Far Clock Region)

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, <i>without</i> MMCM/PLL.							
T _{ICKOFFAR}	Clock-capable clock input and OUTFF <i>without</i> MMCM/PLL (far clock region)	XC7Z010	5.08	5.68	6.65	N/A	ns
		XC7Z015	5.60	6.25	7.21	N/A	ns
		XC7Z020	5.69	6.34	7.40	N/A	ns
		XA7Z010	N/A	N/A	6.65	6.65	ns
		XA7Z020	N/A	N/A	7.40	7.40	ns
		XQ7Z020	N/A	6.34	7.40	7.40	ns

Notes:

- This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

Table 72: Clock-Capable Clock Input to Output Delay With MMCM

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, <i>with</i> MMCM.							
T _{ICKOFFMMCMCC}	Clock-capable clock input and OUTFF <i>with</i> MMCM	XC7Z010	1.04	1.03	1.03	N/A	ns
		XC7Z015	1.05	1.04	1.06	N/A	ns
		XC7Z020	1.05	1.04	1.05	N/A	ns
		XA7Z010	N/A	N/A	1.03	1.03	ns
		XA7Z020	N/A	N/A	1.05	1.05	ns
		XQ7Z020	N/A	1.04	1.05	1.05	ns

Notes:

- This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
- MMCM output jitter is already included in the timing calculation.

Table 73: Clock-Capable Clock Input to Output Delay With PLL

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, <i>with</i> PLL.							
T _{ICKOFFPLLCC}	Clock-capable clock input and OUTFF <i>with</i> PLL	XC7Z010	0.82	0.82	0.82	N/A	ns
		XC7Z015	0.82	0.82	0.82	N/A	ns
		XC7Z020	0.82	0.82	0.82	N/A	ns
		XA7Z010	N/A	N/A	0.82	0.82	ns
		XA7Z020	N/A	N/A	0.82	0.82	ns
		XQ7Z020	N/A	0.82	0.82	0.82	ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. PLL output jitter is already included in the timing calculation.

Table 74: Pin-to-Pin, Clock-to-Out using BUFIO

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flop, Fast Slew Rate, with BUFIO.						
T _{ICKOFCS}	Clock to out of I/O clock	5.14	5.76	6.81	6.81	ns

Device Pin-to-Pin Input Parameter Guidelines

Table 75: Global Clock Input Setup and Hold Without MMCM/PLL with ZHOLD_DELAY on HR I/O Banks

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
Input Setup and Hold Time Relative to Global Clock Input Signal for SSTL15 Standard. ⁽¹⁾							
T _{PSFD} / T _{PHFD}	Full delay (legacy delay or default delay) global clock input and IFF ⁽²⁾ without MMCM/PLL with ZHOLD_DELAY on HR I/O banks	XC7Z010	2.00/−0.17	2.13/−0.17	2.44/−0.17	N/A	ns
		XC7Z015	2.38/−0.18	2.55/−0.18	3.03/−0.18	N/A	ns
		XC7Z020	2.55/−0.25	2.74/−0.25	3.18/−0.25	N/A	ns
		XA7Z010	N/A	N/A	2.44/−0.17	2.44/−0.17	ns
		XA7Z020	N/A	N/A	3.18/−0.25	3.18/−0.25	ns
		XQ7Z020	N/A	2.74/−0.25	3.18/−0.25	3.18/−0.25	ns

Notes:

1. Setup and hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the global clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the global clock input signal using the fastest process, lowest temperature, and highest voltage.
2. IFF = Input flip-flop or latch.

Table 76: Clock-Capable Clock Input Setup and Hold With MMCM

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
Input Setup and Hold Time Relative to Global Clock Input Signal for SSTL15 Standard. ⁽¹⁾							
T _{PSMMCMCC} / T _{PHMMCMCC}	No delay clock-capable clock input and IFF ⁽²⁾ with MMCM	XC7Z010	2.36/−0.62	2.68/−0.62	3.22/−0.62	N/A	ns
		XC7Z015	2.47/−0.62	2.80/−0.62	3.34/−0.62	N/A	ns
		XC7Z020	2.48/−0.62	2.82/−0.62	3.38/−0.62	N/A	ns
		XA7Z010	N/A	N/A	3.22/−0.62	3.22/−0.62	ns
		XA7Z020	N/A	N/A	3.38/−0.62	3.38/−0.62	ns
		XQ7Z020	N/A	2.82/−0.62	3.38/−0.62	3.38/−0.62	ns

Notes:

1. Setup and hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the global clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the global clock input signal using the fastest process, lowest temperature, and highest voltage.
2. IFF = Input flip-flop or latch
3. Use IBIS to determine any duty-cycle distortion incurred using various standards.

Table 77: Clock-Capable Clock Input Setup and Hold With PLL

Symbol	Description	Device	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
Input Setup and Hold Time Relative to Clock-Capable Clock Input Signal for SSTL15 Standard. ⁽¹⁾							
T _{PSPLLCC} / T _{PHPLLCC}	No delay clock-capable clock input and IFF ⁽²⁾ with PLL	XC7Z010	2.67/−0.19	3.03/−0.19	3.64/−0.19	N/A	ns
		XC7Z015	2.78/−0.20	3.15/−0.20	3.76/−0.20	N/A	ns
		XC7Z020	2.79/−0.20	3.17/−0.20	3.80/−0.20	N/A	ns
		XA7Z010	N/A	N/A	3.64/−0.19	3.64/−0.19	ns
		XA7Z020	N/A	N/A	3.80/−0.20	3.80/−0.20	ns
		XQ7Z020	N/A	3.17/−0.20	3.80/−0.20	3.80/−0.20	ns

Notes:

1. Setup and hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the global clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the global clock input signal using the fastest process, lowest temperature, and highest voltage.
2. IFF = Input flip-flop or latch
3. Use IBIS to determine any duty-cycle distortion incurred using various standards.

Table 78: Data Input Setup and Hold Times Relative to a Forwarded Clock Input Pin Using BUFIO

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Input Setup and Hold Time Relative to a Forwarded Clock Input Pin Using BUFIO for SSTL15 Standard.						
T _{PSCS} /T _{PHCS}	Setup and hold of I/O clock	-0.38/1.39	-0.38/1.55	-0.38/1.86	-0.38/1.86	ns

Table 79: Sample Window

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
T _{SAMP}	Sampling error at receiver pins ⁽¹⁾	0.59	0.64	0.70	0.70	ns
T _{SAMP_BUFIO}	Sampling error at receiver pins using BUFIO ⁽²⁾	0.35	0.40	0.46	0.46	ns

Notes:

1. This parameter indicates the total sampling error of the PL DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the MMCM to capture the DDR input registers' edges of operation. These measurements include:
 - CLK0 MMCM jitter
 - MMCM accuracy (phase offset)
 - MMCM phase shift resolution
These measurements do not include package or clock tree skew.
2. This parameter indicates the total sampling error of the PL DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the BUFIO clock network and IDELAY to capture the DDR input registers' edges of operation. These measurements do not include package or clock tree skew.

Additional Package Parameter Guidelines

The parameters in this section provide the necessary values for calculating timing budgets for PL clock transmitter and receiver data-valid windows.

Table 80: Package Skew

Symbol	Description	Device	Package	Value	Units
T _{PKGSKEW}	Package skew ⁽¹⁾	XC7Z010	CLG225	101	ps
			CLG400	155	ps
		XC7Z015	CLG485	182	ps
		XC7Z020	CLG400	166	ps
			CLG484	248	ps
		XA7Z010	CLG225	101	ps
			CLG400	155	ps
		XA7Z020	CLG400	166	ps
			CLG484	248	ps
		XQ7Z020	CL400	166	ps
			CL484	248	ps

Notes:

1. These values represent the worst-case skew between any two SelectIO resources in the package: shortest delay to longest delay from die pad to ball.
2. Package delay information is available for these device/package combinations. This information can be used to deskew the package.

GTP Transceiver Specifications (Only available in the XC7Z015)

GTP Transceiver DC Input and Output Levels

Table 81 summarizes the DC output specifications of the GTP transceivers in the XC7Z015. Consult the *7 Series FPGAs GTP Transceiver User Guide* (UG482) for further details.

Table 81: GTP Transceiver DC Specifications

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
DV _{PPOUT}	Differential peak-to-peak output voltage ⁽¹⁾	Transmitter output swing is set to maximum setting	–	–	1000	mV
V _{CMOUTDC}	DC common mode output voltage	Equation based	$V_{MGTAVTT} - DV_{PPOUT}/4$			mV
R _{OUT}	Differential output resistance		–	100	–	Ω
V _{CMOUTAC}	Common mode output voltage: AC coupled		$1/2 V_{MGTAVTT}$			mV
T _{OSKEW}	Transmitter output pair (TXP and TXN) intra-pair skew		–	–	12	ps
DV _{PPIN}	Differential peak-to-peak input voltage	External AC coupled	150	–	2000	mV
V _{IN}	Absolute input voltage	DC coupled $V_{MGTAVTT} = 1.2V$	–200	–	$V_{MGTAVTT}$	mV
V _{CMIN}	Common mode input voltage	DC coupled $V_{MGTAVTT} = 1.2V$	–	$2/3 V_{MGTAVTT}$	–	mV
R _{IN}	Differential input resistance		–	100	–	Ω
C _{EXT}	Recommended external AC coupling capacitor ⁽²⁾		–	100	–	nF

Notes:

- The output swing and preemphasis levels are programmable using the attributes discussed in the *7 Series FPGAs GTP Transceiver User Guide* (UG482) and can result in values lower than reported in this table.
- Other values can be used as appropriate to conform to specific protocols and standards.

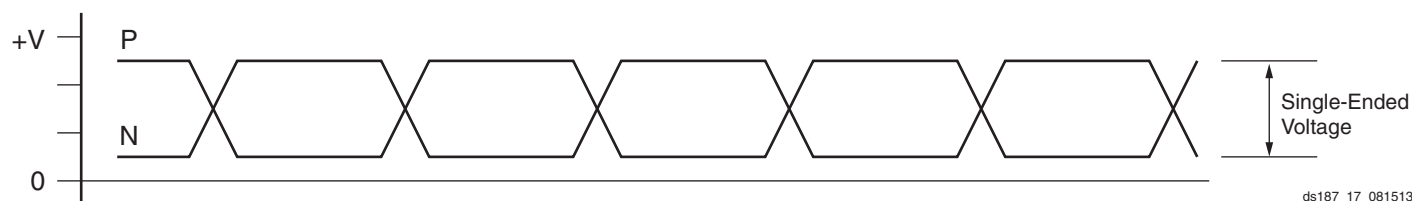


Figure 17: Single-Ended Peak-to-Peak Voltage

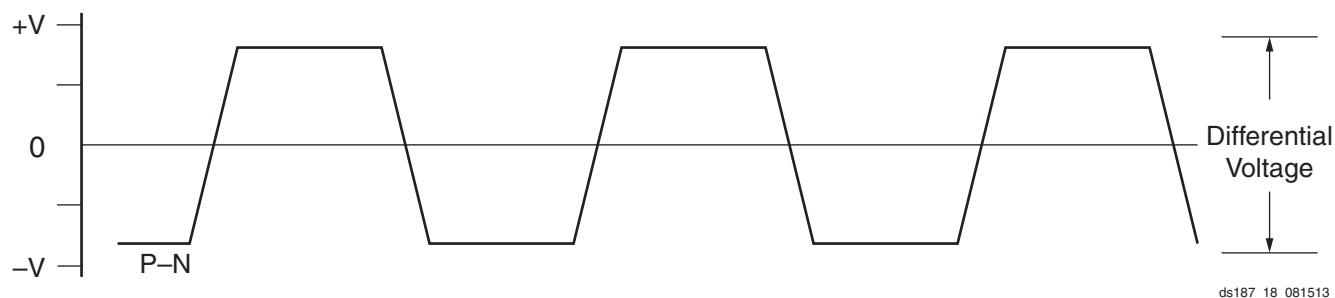


Figure 18: Differential Peak-to-Peak Voltage

Table 82 summarizes the DC specifications of the clock input of the GTP transceiver. Consult the *7 Series FPGAs GTP Transceiver User Guide* ([UG482](#)) for further details.

Table 82: GTP Transceiver Clock DC Input Level Specification

Symbol	DC Parameter	Min	Typ	Max	Units
V_{IDIFF}	Differential peak-to-peak input voltage	350	–	2000	mV
R_{IN}	Differential input resistance	–	100	–	Ω
C_{EXT}	Required external AC coupling capacitor	–	100	–	nF

GTP Transceiver Switching Characteristics

Consult the *7 Series FPGAs GTP Transceiver User Guide* ([UG482](#)) for further information.

Table 83: GTP Transceiver Performance

Symbol	Description	Output Divider	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
F_{GTPMAX}	Maximum GTP transceiver data rate		6.25	6.25	3.75	N/A	Gb/s
F_{GTPMIN}	Minimum GTP transceiver data rate		0.500	0.500	0.500	N/A	Gb/s
$F_{GTPRANGE}$	PLL line rate range	1	3.2–6.25	3.2–6.25	3.2–3.75	N/A	Gb/s
		2	1.6–3.3	1.6–3.3	1.6–3.2	N/A	Gb/s
		4	0.8–1.65	0.8–1.65	0.8–1.6	N/A	Gb/s
		8	0.5–0.825	0.5–0.825	0.5–0.8	N/A	Gb/s
$F_{GTPPLLRange}$	GTP transceiver PLL frequency range		1.6–3.3	1.6–3.3	1.6–3.3	N/A	GHz

Table 84: GTP Transceiver Dynamic Reconfiguration Port (DRP) Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
$F_{GTPDRCLK}$	GTPDRCLK maximum frequency	175	175	156	N/A	MHz

Table 85: GTP Transceiver Reference Clock Switching Characteristics

Symbol	Description	Conditions	All Speed Grades			Units
			Min	Typ	Max	
F_{GCLK}	Reference clock frequency range		60	–	660	MHz
T_{RCLK}	Reference clock rise time	20% – 80%	–	200	–	ps
T_{FCLK}	Reference clock fall time	80% – 20%	–	200	–	ps
T_{DCREF}	Reference clock duty cycle	Transceiver PLL only	40	–	60	%

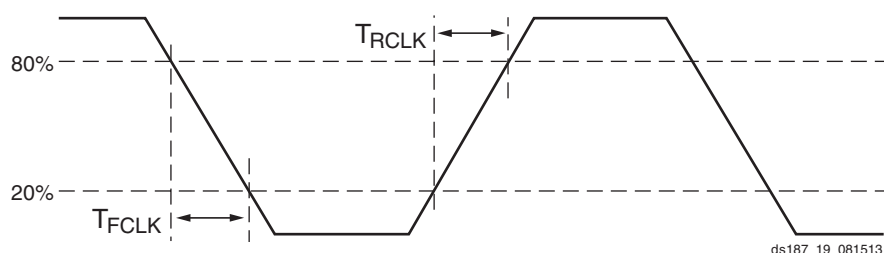


Figure 19: Reference Clock Timing Parameters

Table 86: GTP Transceiver PLL/Lock Time Adaptation

Symbol	Description	Conditions	All Speed Grades			Units
			Min	Typ	Max	
T _{LOCK}	Initial PLL lock		–	–	1	ms
T _{DLOCK}	Clock recovery phase acquisition and adaptation time.	After the PLL is locked to the reference clock, this is the time it takes to lock the clock data recovery (CDR) to the data present at the input.	–	50,000	2.3 x10 ⁶	UI

Table 87: GTP Transceiver User Clock Switching Characteristics⁽¹⁾

Symbol	Description	Conditions	Speed Grade				Units
			-3	-2	-1C/-1I	-1Q	
F _{TXOUT}	TXOUTCLK maximum frequency		390.625	390.625	234.375	N/A	MHz
F _{RXOUT}	RXOUTCLK maximum frequency		390.625	390.625	234.375	N/A	MHz
F _{TXIN}	TXUSRCLK maximum frequency	16-bit data path	390.625	390.625	234.375	N/A	MHz
F _{RXIN}	RXUSRCLK maximum frequency	16-bit data path	390.625	390.625	234.375	N/A	MHz
F _{TXIN2}	TXUSRCLK2 maximum frequency	16-bit data path	390.625	390.625	234.375	N/A	MHz
F _{RXIN2}	RXUSRCLK2 maximum frequency	16-bit data path	390.625	390.625	234.375	N/A	MHz

Notes:

1. Clocking must be implemented as described in the *7 Series FPGAs GTP Transceiver User Guide* ([UG482](#)).

Table 88: GTP Transceiver Transmitter Switching Characteristics

Symbol	Description	Condition	Min	Typ	Max	Units
F _{GTPTX}	Serial data rate range		0.500	–	F _{GTPMAX}	Gb/s
T _{RTX}	TX rise time	20%–80%	–	50	–	ps
T _{FTX}	TX fall time	80%–20%	–	50	–	ps
T _{LLSKEW}	TX lane-to-lane skew ⁽¹⁾		–	–	500	ps
V _{TXOOBVDPP}	Electrical idle amplitude		–	–	20	mV
T _{TXOOBTRANSITION}	Electrical idle transition time		–	–	140	ns
TJ _{6.25}	Total Jitter ⁽²⁾⁽³⁾	6.25 Gb/s	–	–	0.30	UI
DJ _{6.25}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.15	UI
TJ _{5.0}	Total Jitter ⁽²⁾⁽³⁾	5.0 Gb/s	–	–	0.30	UI
DJ _{5.0}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.15	UI
TJ _{4.25}	Total Jitter ⁽²⁾⁽³⁾	4.25 Gb/s	–	–	0.30	UI
DJ _{4.25}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.15	UI
TJ _{3.75}	Total Jitter ⁽²⁾⁽³⁾	3.75 Gb/s	–	–	0.30	UI
DJ _{3.75}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.15	UI
TJ _{3.2}	Total Jitter ⁽²⁾⁽³⁾	3.20 Gb/s ⁽⁴⁾	–	–	0.2	UI
DJ _{3.2}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.1	UI
TJ _{3.2L}	Total Jitter ⁽²⁾⁽³⁾	3.20 Gb/s ⁽⁵⁾	–	–	0.32	UI
DJ _{3.2L}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.16	UI
TJ _{2.5}	Total Jitter ⁽²⁾⁽³⁾	2.5 Gb/s ⁽⁶⁾	–	–	0.20	UI
DJ _{2.5}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.08	UI
TJ _{1.25}	Total Jitter ⁽²⁾⁽³⁾	1.25 Gb/s ⁽⁷⁾	–	–	0.15	UI
DJ _{1.25}	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.06	UI
TJ ₅₀₀	Total Jitter ⁽²⁾⁽³⁾	500 Mb/s	–	–	0.1	UI
DJ ₅₀₀	Deterministic Jitter ⁽²⁾⁽³⁾		–	–	0.03	UI

Notes:

- Using same REFCLK input with TX phase alignment enabled for up to four consecutive transmitters (one fully populated GTP Quad).
- Using PLL[0/1]_FBDIV = 2, 20-bit internal data width. These values are NOT intended for protocol specific compliance determinations.
- All jitter values are based on a bit-error ratio of 1e⁻¹².
- PLL frequency at 3.2 GHz and TXOUT_DIV = 2.
- PLL frequency at 1.6 GHz and TXOUT_DIV = 1.
- PLL frequency at 2.5 GHz and TXOUT_DIV = 2.
- PLL frequency at 2.5 GHz and TXOUT_DIV = 4.

Table 89: GTP Transceiver Receiver Switching Characteristics

Symbol	Description		Min	Typ	Max	Units
F _{GTPRX}	Serial data rate	RX oversampler not enabled	0.500	–	F _{GTPMAX}	Gb/s
T _{RXELECIDLE}	Time for RXELEC_IDLE to respond to loss or restoration of data		–	10	–	ns
RX _{OOBVDPP}	OOB detect threshold peak-to-peak		60	–	150	mV
RX _{SST}	Receiver spread-spectrum tracking ⁽¹⁾	Modulated @ 33 KHz	–5000	–	5000	ppm
RX _{RL}	Run length (CID)		–	–	512	UI
RX _{PPMTOL}	Data/REFCLK PPM offset tolerance		–1250	–	1250	ppm
SJ Jitter Tolerance ⁽²⁾						
JT_SJ _{6.25}	Sinusoidal Jitter ⁽³⁾	6.25 Gb/s	0.44	–	–	UI
JT_SJ _{5.0}	Sinusoidal Jitter ⁽³⁾	5.0 Gb/s	0.44	–	–	UI
JT_SJ _{4.25}	Sinusoidal Jitter ⁽³⁾	4.25 Gb/s	0.44	–	–	UI
JT_SJ _{3.75}	Sinusoidal Jitter ⁽³⁾	3.75 Gb/s	0.44	–	–	UI
JT_SJ _{3.2}	Sinusoidal Jitter ⁽³⁾	3.2 Gb/s ⁽⁴⁾	0.45	–	–	UI
JT_SJ _{3.2L}	Sinusoidal Jitter ⁽³⁾	3.2 Gb/s ⁽⁵⁾	0.45	–	–	UI
JT_SJ _{2.5}	Sinusoidal Jitter ⁽³⁾	2.5 Gb/s ⁽⁶⁾	0.5	–	–	UI
JT_SJ _{1.25}	Sinusoidal Jitter ⁽³⁾	1.25 Gb/s ⁽⁷⁾	0.5	–	–	UI
JT_SJ ₅₀₀	Sinusoidal Jitter ⁽³⁾	500 Mb/s	0.4	–	–	UI
SJ Jitter Tolerance with Stressed Eye ⁽²⁾						
JT_TJSE _{3.2}	Total Jitter with Stressed Eye ⁽⁸⁾	3.2 Gb/s	0.70	–	–	UI
JT_TJSE _{6.25}		6.25 Gb/s	0.70	–	–	UI
JT_SJSE _{3.2}	Sinusoidal Jitter with Stressed Eye ⁽⁸⁾	3.2 Gb/s	0.1	–	–	UI
JT_SJSE _{6.25}		6.25 Gb/s	0.1	–	–	UI

Notes:

1. Using RXOUT_DIV = 1, 2, and 4.
2. All jitter values are based on a bit error ratio of 1e^{–12}.
3. The frequency of the injected sinusoidal jitter is 10 MHz.
4. PLL frequency at 3.2 GHz and RXOUT_DIV = 2.
5. PLL frequency at 1.6 GHz and RXOUT_DIV = 1.
6. PLL frequency at 2.5 GHz and RXOUT_DIV = 2.
7. PLL frequency at 2.5 GHz and RXOUT_DIV = 4.
8. Composite jitter.

GTP Transceiver Protocol Jitter Characteristics

For Table 90 through Table 94, the 7 Series FPGAs GTP Transceiver User Guide (UG482) contains recommended settings for optimal usage of protocol specific characteristics.

Table 90: Gigabit Ethernet Protocol Characteristics

Description	Line Rate (Mb/s)	Min	Max	Units
Gigabit Ethernet Transmitter Jitter Generation				
Total transmitter jitter (T _{TJ})	1250	–	0.24	UI
Gigabit Ethernet Receiver High Frequency Jitter Tolerance				
Total receiver jitter tolerance	1250	0.749	–	UI

Table 91: XAUI Protocol Characteristics

Description	Line Rate (Mb/s)	Min	Max	Units
XAUI Transmitter Jitter Generation				
Total transmitter jitter (T _{TJ})	3125	–	0.35	UI
XAUI Receiver High Frequency Jitter Tolerance				
Total receiver jitter tolerance	3125	0.65	–	UI

Table 92: PCI Express Protocol Characteristics⁽¹⁾

Standard	Description	Line Rate (Mb/s)	Min	Max	Units
PCI Express Transmitter Jitter Generation					
PCI Express Gen 1	Total transmitter jitter	2500	–	0.25	UI
PCI Express Gen 2	Total transmitter jitter	5000	–	0.25	UI
PCI Express Receiver High Frequency Jitter Tolerance					
PCI Express Gen 1	Total receiver jitter tolerance	2500	0.65	–	UI
PCI Express Gen 2 ⁽²⁾	Receiver inherent timing error	5000	0.40	–	UI
	Receiver inherent deterministic timing error		0.30	–	UI

Notes:

1. Tested per card electromechanical (CEM) methodology.
2. Using common REFCLK.

Table 93: CEI-6G Protocol Characteristics

Description	Line Rate (Mb/s)	Interface	Min	Max	Units
CEI-6G Transmitter Jitter Generation					
Total transmitter jitter ⁽¹⁾	4976–6375	CEI-6G-SR	–	0.3	UI
CEI-6G Receiver High Frequency Jitter Tolerance					
Total receiver jitter tolerance ⁽¹⁾	4976–6375	CEI-6G-SR	0.6	–	UI

Notes:

1. Tested at most commonly used line rate of 6250 Mb/s using 390.625 MHz reference clock.

Table 94: CPRI Protocol Characteristics

Description	Line Rate (Mb/s)	Min	Max	Units
CPRI Transmitter Jitter Generation				
Total transmitter jitter	614.4	–	0.35	UI
	1228.8	–	0.35	UI
	2457.6	–	0.35	UI
	3072.0	–	0.35	UI
	4915.2	–	0.3	UI
	6144.0	–	0.3	UI
CPRI Receiver Frequency Jitter Tolerance				
Total receiver jitter tolerance	614.4	0.65	–	UI
	1228.8	0.65	–	UI
	2457.6	0.65	–	UI
	3072.0	0.65	–	UI
	4915.2 ⁽¹⁾	0.60	–	UI
	6144.0 ⁽¹⁾	0.60	–	UI

Notes:

1. Tested to CEI-6G-SR.

Integrated Interface Block for PCI Express Designs Switching Characteristics (XC7Z015 Only)

This block is only available in the XC7Z015. More information and documentation on solutions for PCI Express designs can be found at: www.xilinx.com/technology/protocols/pciexpress.htm

Table 95: Maximum Performance for PCI Express Designs (XC7Z015 only)

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
F _{PIPECLK}	Pipe clock maximum frequency	250.00	250.00	250.00	N/A	MHz
F _{USERCLK}	User clock maximum frequency	250.00	250.00	250.00	N/A	MHz
F _{USERCLK2}	User clock 2 maximum frequency	250.00	250.00	250.00	N/A	MHz
F _{DRPCLK}	DRP clock maximum frequency	250.00	250.00	250.00	N/A	MHz

XADC Specifications

Table 96: XADC Specifications

Parameter	Symbol	Comments/Conditions	Min	Typ	Max	Units
V _{CCADC} = 1.8V ± 5%, V _{REFP} = 1.25V, V _{REFN} = 0V, ADCCLK = 26 MHz, −55°C ≤ T _j ≤ 125°C, Typical values at T _j =+40°C						
ADC Accuracy ⁽¹⁾						
Resolution			12	–	–	Bits
Integral Nonlinearity ⁽²⁾	INL	−40°C ≤ T _j ≤ 100°C	–	–	±2	LSBs
		−55°C ≤ T _j < −40°C; 100°C < T _j ≤ 125°C	–	–	±3	LSBs
Differential Nonlinearity	DNL	No missing codes, guaranteed monotonic	–	–	±1	LSBs
Offset Error	Unipolar	−40°C ≤ T _j ≤ 100°C	–	–	±8	LSBs
		−55°C ≤ T _j < −40°C; 100°C < T _j ≤ 125°C			±12	LSBs
	Bipolar	−55°C ≤ T _j ≤ 125°C	–	–	±4	LSBs
Gain Error			–	–	±0.5	%
Offset Matching			–	–	4	LSBs
Gain Matching			–	–	0.3	%
Sample Rate			0.1	–	1	MS/s
Signal to Noise Ratio ⁽²⁾	SNR	F _{SAMPLE} = 500KS/s, F _{IN} = 20KHz	60	–	–	dB
RMS Code Noise		External 1.25V reference	–	–	2	LSBs
		On-chip reference	–	3	–	LSBs
Total Harmonic Distortion ⁽²⁾	THD	F _{SAMPLE} = 500KS/s, F _{IN} = 20KHz	70	–	–	dB
Analog Inputs ⁽³⁾						
ADC Input Ranges		Unipolar operation	0	–	1	V
		Bipolar operation	−0.5	–	+0.5	V
		Unipolar common mode range (FS input)	0	–	+0.5	V
		Bipolar common mode range (FS input)	+0.5	–	+0.6	V
Maximum External Channel Input Ranges		Adjacent analog channels set within these ranges should not corrupt measurements on adjacent channels	−0.1	–	V _{CCADC}	V
Auxiliary Channel Full Resolution Bandwidth	FRBW		250	–	–	KHz
On-Chip Sensors						
Temperature Sensor Error		−40°C ≤ T _j ≤ 100°C	–	–	±4	°C
		−55°C ≤ T _j < −40°C; 100°C < T _j ≤ 125°C	–	–	±6	°C
Supply Sensor Error		−40°C ≤ T _j ≤ 100°C	–	–	±1	%
		−55°C ≤ T _j < −40°C; 100°C < T _j ≤ 125°C	–	–	±2	%
Conversion Rate ⁽⁴⁾						
Conversion Time - Continuous	t _{CONV}	Number of ADCCLK cycles	26	–	32	Cycles
Conversion Time - Event	t _{CONV}	Number of CLK cycles	–	–	21	Cycles
DRP Clock Frequency	DCLK	DRP clock frequency	8	–	250	MHz
ADC Clock Frequency	ADCCLK	Derived from DCLK	1	–	26	MHz
DCLK Duty Cycle			40	–	60	%

Table 96: XADC Specifications (Cont'd)

Parameter	Symbol	Comments/Conditions	Min	Typ	Max	Units
XADC Reference⁽⁵⁾						
External Reference	V _{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
On-Chip Reference		Ground V _{REFP} pin to AGND, –40°C ≤ T _j ≤ 100°C	1.2375	1.25	1.2625	V
		Ground V _{REFP} pin to AGND, –55°C ≤ T _j < –40°C; 100°C < T _j ≤ 125°C	1.225	1.25	1.275	V

Notes:

- Offset and gain errors are removed by enabling the XADC automatic gain calibration feature. The values are specified for when this feature is enabled.
- Only specified for bitstream option XADCEnhancedLinearity = ON.
- See the ADC chapter in the *7 Series FPGAs and Zynq-7000 All Programmable SoC XADC Dual 12-Bit 1 MSPS Analog-to-Digital Converter User Guide* (UG480) for a detailed description.
- See the Timing chapter in the *7 Series FPGAs and Zynq-7000 All Programmable SoC XADC Dual 12-Bit 1 MSPS Analog-to-Digital Converter User Guide* (UG480) for a detailed description.
- Any variation in the reference voltage from the nominal V_{REFP} = 1.25V and V_{REFN} = 0V will result in a deviation from the ideal transfer function. This also impacts the accuracy of the internal sensor measurements (i.e., temperature and power supply). However, for external ratiometric type applications allowing reference to vary by ±4% is permitted.

Configuration Switching Characteristics

Table 97: Configuration Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-2	-1C/-1I	-1Q	
Power-up Timing Characteristics						
T _{PL} ⁽¹⁾	Program latency	5.00	5.00	5.00	5.00	ms, Max
T _{POR}	Power-on reset (50 ms ramp rate time)	10/50	10/50	10/50	10/50	ms, Min/Max
	Power-on reset (1 ms ramp rate time) with the power-on reset override function disabled; (devcfg.CTRL.PCFG_POR_CNT_4K = 0). ⁽²⁾	10/35	10/35	10/35	10/35	ms, Min/Max
	Power-on reset (1 ms ramp rate time) with the power-on reset override function enabled; (devcfg.CTRL.PCFG_POR_CNT_4K = 1). ⁽²⁾	2/8	2/8	2/8	2/8	ms, Min/Max
T _{PROGRAM}	Program pulse width	250.00	250.00	250.00	250.00	ns, Min
Boundary-Scan Port Timing Specifications						
T _{TAPTCK} /T _{TCKTAP}	TMS and TDI setup/hold	3.00/2.00	3.00/2.00	3.00/2.00	3.00/2.00	ns, Min
T _{TCKTDO}	TCK falling edge to TDO output	7.00	7.00	7.00	7.00	ns, Max
F _{TCK}	TCK frequency	66.00	66.00	66.00	66.00	MHz, Max
Internal Configuration Access Port						
F _{ICAPCK}	Internal configuration access port (ICAPE2)	100.00	100.00	100.00	100.00	MHz, Max
Device DNA Access Port						
F _{DNACK}	DNA access port (DNA_PORT)	100.00	100.00	100.00	100.00	MHz, Max

Notes:

- To support longer delays in configuration, use the design solutions described in the *7 Series FPGA Configuration User Guide* (UG470).
- For non-secure boot only. Measurement is made when the PS is already powered and stable, before power cycling the PL.

eFUSE Programming Conditions

Table 98 lists the programming conditions specifically for eFUSE. For more information, see the *7 Series FPGA Configuration User Guide* (UG470).

Table 98: eFUSE Programming Conditions⁽¹⁾

Symbol	Description	Min	Typ	Max	Units
I_{PLFS}	PL V_{CCAUX} supply current	–	–	115	mA
I_{PSFS}	PS V_{CCAUX} supply current	–	–	115	mA
t_j	Temperature range	15	–	125	°C

Notes:

1. The Zynq-7000 device must not be configured during eFUSE programming.

Revision History

The following table shows the revision history for this document:

Date	Version	Description of Revisions
05/07/2012	1.0	Initial Xilinx release.
06/27/2012	1.1	Updated the descriptions, changed V_{IN} , Note 3, Note 4, and added V_{PREF} , V_{PIN} , and Note 5 in Table 1. In Table 2, updated descriptions and notes. Updated Table 3 and added R_{IN_TERM} . Removed I_{CCMIOQ} from Table 5. Removed I_{CCMIOQ} and updated XC7Z020 in Table 6. Updated LVCMOS12, SSTL135, and SSTL15 in Table 10. Updated Table 18. In PS Performance Characteristics section, added timing diagrams and revised many tables. Updated Table 48 and removed notes 2 and 3. Added Note 2 and Note 3 to Table 49. Changed Table 51 by adding $T_{IOIBUFDISABLE}$. Removed many of the combinatorial delay specifications and T_{CINCK}/T_{CKCIN} from Table 58. In Table 96 updated Offset Error and Matching descriptions and Gain Error and Matching descriptions, and added Note 2 to Integral Nonlinearity.
09/12/2012	1.2	Changed Note 3 and added Note 5 in Table 1. Updated T_j in Table 2, also revised Note 4 and Note 9. Updated specifications including R_{IN_TERM} in Table 3. Added Table 4. Updated the XC7Z020 specifications in Table 6. Updated standards in Table 8. Updated specifications in Table 12. Updated the AC Switching Characteristics section for the ISE tools 14.2 speed specifications throughout the document. In PS Performance Characteristics section introduction, revised tables, updated Figure 4, and added Figure 5. Updated parameters in Figure 5 through Figure 13. Updated values in Table 17. Added Note 2 to Table 23. Added Note 3 to Table 34. Updated descriptions and revised $F_{MSPICLK}$ in Table 39. Updated Note 3 in Table 49. Changed F_{PFDMAX} conditions in Table 68 and Table 69. Updated devices and added values to Table 80.
02/11/2013	1.3	Updated the AC Switching Characteristics based upon ISE tools 14.4 and Vivado tools 2012.4, both at v1.05 for the -3, -2, and -1 speed specifications throughout the document. Updated Table 15 and Table 16 to the product status of production for the XC7Z020 devices with -2 and -1 speed specifications. Updated description in Introduction. Revised V_{PIN} in Table 1. Revised V_{PIN} and I_{IN} and added Note 2 to Table 2. Clarified PS specifications, added C_{PIN} , and removed Note 3 on I_{RPD} in Table 3. Added values to Table 5. Updated Power Supply Requirements section. Revised descriptions in Table 7. Revised Note 1, removed LVTTTL, notes 2 and 3, and added SSTL135 to Table 8. Added Table 9. Removed HSTL_I_12 and SSTL_12 from Table 10. Removed DIFF_SSTL12 from Table 12. Revise in V_{CCO} min/max in Table 13. Many changes to the PS Switching Characteristics section including adding tables, figures, notes with test conditions where applicable. In Table 17, updated the 6:2:1 clock ratio frequencies. Updated minimum value for $T_{ULPIDCK}$ in Table 33. Added a 2:1 memory controller section to Table 49. Updated Note 1 in Table 65. Updated Note 1 and Note 2 in Table 80. Updated the rows on offset error and matching and gain error and matching and the maximum external channel input ranges in Table 96. Added Internal Configuration Access Port section to Table 97.

Date	Version	Description of Revisions
02/14/2013	1.4	Corrected $T_{QSPICKD2}$ minimum equation in Table 32 . Updated timing parameter names in Figure 3 and Figure 4 to match those in the accompanying table.
02/19/2013	1.4.1	Corrected version history.
03/19/2013	1.5	Updated Table 15 and Table 16 to the product status of production for the XC7Z010 devices with -2 and -1 speed specifications. Updated Figure 3 by adding OUT0. Added Note 2 to Table 31 . Added Table 36 and Figure 8 .
04/24/2013	1.6	All the devices listed in this data sheet are production released. Updated the AC Switching Characteristics based upon ISE tools 14.5 and Vivado tools 2013.1, both at v1.06 for the -3, -2, and -1 speed specifications throughout the document. Updated Table 15 and Table 16 for production release of the XC7Z010 and XC7Z020 in the -3 speed designations. Removed the <i>PS Power-on Reset</i> section. Updated the PS—PL Power Sequencing section. In Table 1 , revised V_{IN} (I/O input voltage) to match values in Table 4 , and combined Note 4 with old Note 5 and then added new Note 6 . Revised V_{IN} description and added Note 8 in Table 2 . Updated first 3 rows in Table 4 . Revised $PCI33_3$ voltage minimum in Table 10 to match values in Table 1 and Table 4 . Added Note 1 to Table 13 . Clarified the load conditions in Table 32 by adding new data. Clarified title of Table 49 . Throughout the data sheet (Table 58 , Table 59 , Table 60 , and Table 75) removed the obvious note “A Zero “0” Hold Time listing indicates no hold time or a negative hold time.”
07/08/2013	1.7	Added Note 5 to Table 2 . Revised the frequency of CPU clock performance (6:2:1) in Table 17 . Updated F_{DDR3L_MAX} values in Table 18 . Moved and added F_{AXI_MAX} to Table 19 . Updated the minimum $T_{DQVALID}$ values in Table 24 and Table 25 . In Table 35 , corrected the F_{SDSCLK} maximum value. In Table 36 , corrected F_{SDSCLK} and fixed the $F_{SDIDCLK}$ typographical unit error. Values in Table 74 and Table 78 were reported incorrectly and have been updated to match speed specifications.
09/12/2013	1.8	Added the XC7Z015 throughout the document. The XC7Z015 is the only device in this data sheet that includes GTP transceivers. Added the GTP transceivers specifications to Table 1 , Table 2 , and Table 7 , and the PL Power-On/Off Power Supply Sequencing , PS—PL Power Sequencing , GTP Transceiver Specifications (Only available in the XC7Z015) , Integrated Interface Block for PCI Express Designs Switching Characteristics (XC7Z015 Only) and sections. Added USRCCLK Output section and clarified values for T_{POR} in Table 97 . Added I_{PSFS} to Table 98 . Updated Notice of Disclaimer .
11/26/2013	1.9	Added specifications for the XQ7Z020 with the -1Q speed specification/temperature range. Added specifications for the XA7Z010 and XA7Z020 with the -1Q speed specification/temperature range. Removed Note 1 and Note 2 from Table 6 . Added Table 14 . Updated Table 96 specifications. In Table 97 , removed the USRCCLK Output section, added T_{PL} , $T_{PROGRAM}$, Note 1 , and the Device DNA Access Port section, and updated the T_{POR} description.

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